

This IC is a protection IC for lithium-ion / lithium polymer rechargeable batteries, which includes high-accuracy voltage detection circuits and delay circuits. It is suitable for protecting 1-cell lithium-ion / lithium polymer rechargeable battery packs from overcharge, overdischarge, and overcurrent.

**Caution** This product can be used in vehicle equipment and in-vehicle equipment. Before using the product for these purposes, it is imperative to contact our sales representatives.

## ■ Features

- High-accuracy voltage detection circuit
 

|                                           |                                  |                  |
|-------------------------------------------|----------------------------------|------------------|
| Overcharge detection voltage              | 3.500 V to 4.800 V (5 mV step)   | Accuracy ±15 mV  |
| Overcharge release voltage                | 3.100 V to 4.800 V <sup>*1</sup> | Accuracy ±50 mV  |
| Overdischarge detection voltage           | 2.000 V to 3.000 V (10 mV step)  | Accuracy ±50 mV  |
| Overdischarge release voltage             | 2.000 V to 3.400 V <sup>*2</sup> | Accuracy ±75 mV  |
| Discharge overcurrent 1 detection voltage | 5 mV to 100 mV (0.5 mV step)     | Accuracy ±1.5 mV |
| Discharge overcurrent 2 detection voltage | 10 mV to 100 mV (1 mV step)      | Accuracy ±3 mV   |
| Load short-circuiting detection voltage   | 20 mV to 100 mV (1 mV step)      | Accuracy ±5 mV   |
|                                           | 101 mV to 300 mV (1 mV step)     | Accuracy ±10 mV  |
| Charge overcurrent detection voltage      | -100 mV to -5 mV (0.5 mV step)   | Accuracy ±1.5 mV |
- Detection delay times are generated only by an internal circuit (external capacitors are unnecessary).
- Discharge overcurrent control function
 

|                                                    |                                                                                   |
|----------------------------------------------------|-----------------------------------------------------------------------------------|
| Release condition of discharge overcurrent status: | Load disconnection                                                                |
| Release voltage of discharge overcurrent status:   | Discharge overcurrent release voltage ( $V_{RIOV}$ ) = $V_{DD} \times 0.8$ (typ.) |
- 0 V battery charge: Enabled, inhibited
- Power-down function: Available, unavailable
- High-withstand voltage: VM pin and CO pin: Absolute maximum rating 28 V
- Wide operation temperature range:  $T_a = -40^\circ\text{C}$  to  $+125^\circ\text{C}$
- Low current consumption
 

|                       |                                                                              |
|-----------------------|------------------------------------------------------------------------------|
| During operation:     | 2.0 $\mu\text{A}$ typ., 4.0 $\mu\text{A}$ max. ( $T_a = +25^\circ\text{C}$ ) |
| During power-down:    | 50 nA max. ( $T_a = +25^\circ\text{C}$ )                                     |
| During overdischarge: | 0.5 $\mu\text{A}$ max. ( $T_a = +25^\circ\text{C}$ )                         |
- Lead-free (Sn 100%), halogen-free
- AEC-Q100 in process<sup>\*3</sup>

- \*1. Overcharge release voltage = Overcharge detection voltage - Overcharge hysteresis voltage  
(Overcharge hysteresis voltage can be selected as 0 V or from a range of 0.1 V to 0.4 V in 50 mV step.)
- \*2. Overdischarge release voltage = Overdischarge detection voltage + Overdischarge hysteresis voltage  
(Overdischarge hysteresis voltage can be selected as 0 V or from a range of 0.1 V to 0.7 V in 100 mV step.)
- \*3. Contact our sales representatives for details.

## ■ Applications

- Lithium-ion rechargeable battery pack
- Lithium polymer rechargeable battery pack

## ■ Package

- SOT-23-6

■ **Block Diagram**

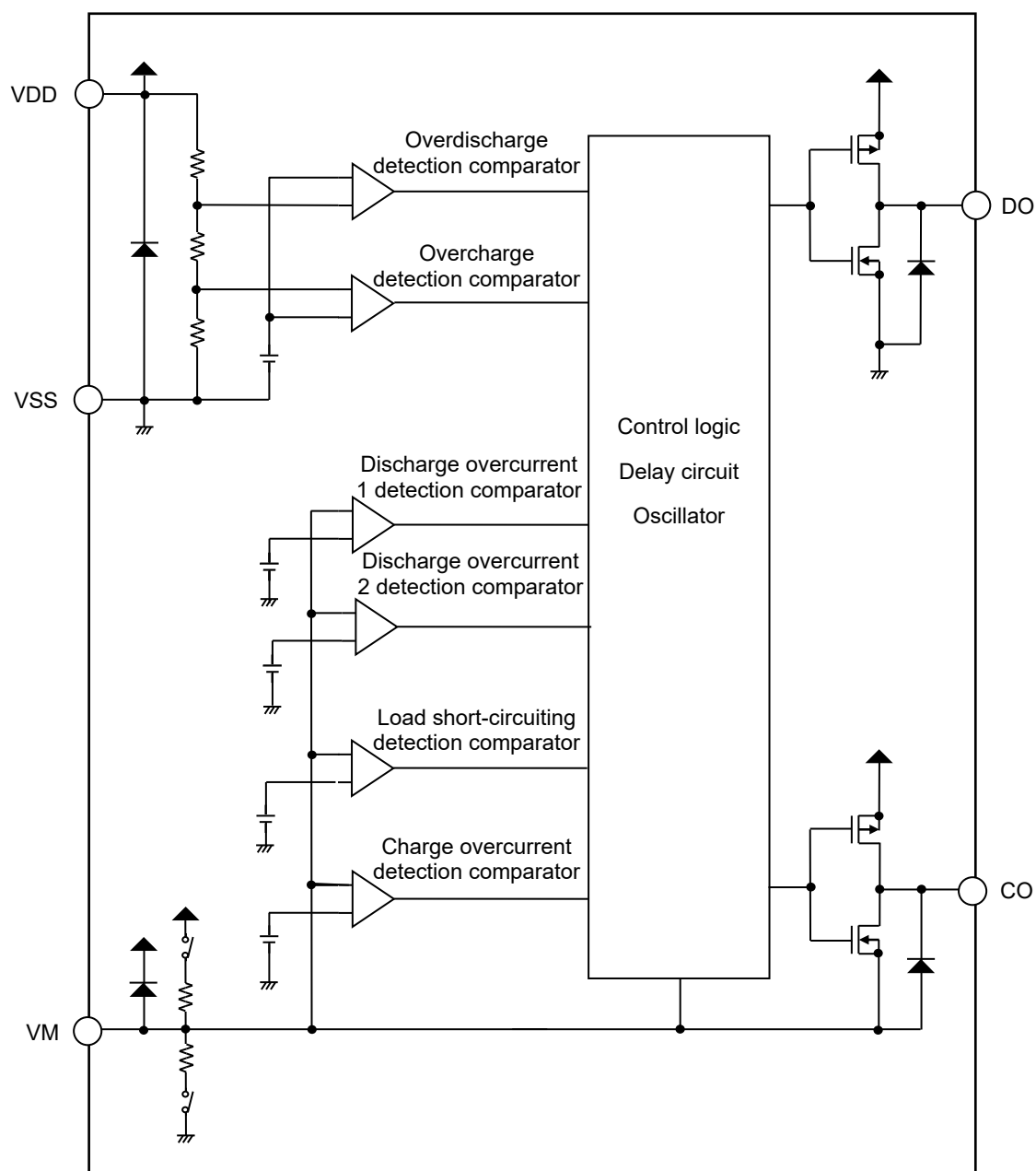


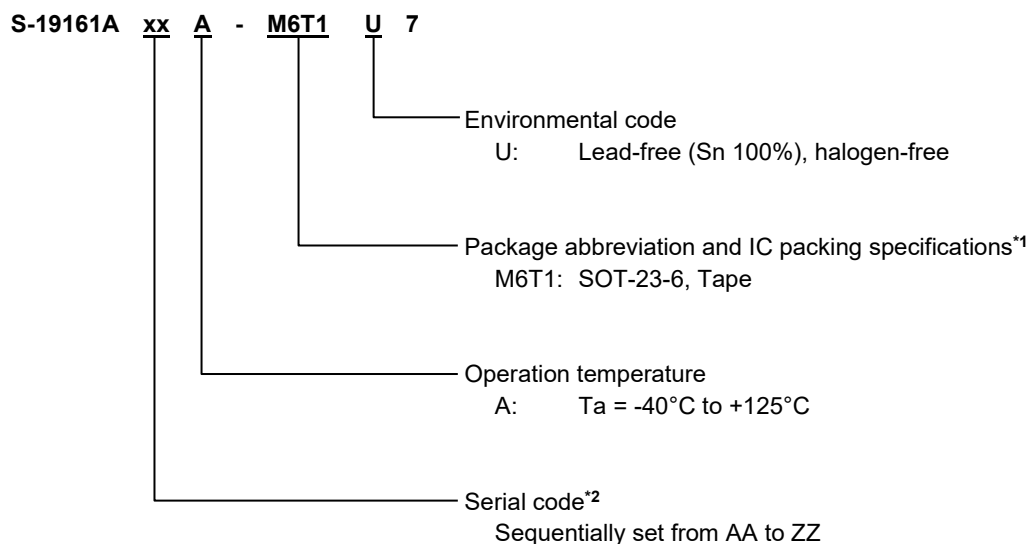
Figure 1

## ■ AEC-Q100 in Process

Contact our sales representatives for details of AEC-Q100 reliability specification.

## ■ Product Name Structure

### 1. Product name



\*1. Refer to the tape drawing.

\*2. Refer to "3. Product name list".

### 2. Package

**Table 1 Package Drawing Codes**

| Package Name | Dimension    | Tape         | Reel         |
|--------------|--------------|--------------|--------------|
| SOT-23-6     | MP006-A-P-SD | MP006-A-C-SD | MP006-A-R-SD |

### 3. Product name list

**Table 2 (1 / 2)**

| Product Name       | Overcharge<br>Detection<br>Voltage<br>[V <sub>CU</sub> ] | Overcharge<br>Release<br>Voltage<br>[V <sub>CL</sub> ] | Overdischarge<br>Detection<br>Voltage<br>[V <sub>DL</sub> ] | Overdischarge<br>Release<br>Voltage<br>[V <sub>DU</sub> ] | Discharge<br>Overcurrent 1<br>Detection Voltage<br>[V <sub>DIOV1</sub> ] | Discharge<br>Overcurrent 2<br>Detection Voltage<br>[V <sub>DIOV2</sub> ] |
|--------------------|----------------------------------------------------------|--------------------------------------------------------|-------------------------------------------------------------|-----------------------------------------------------------|--------------------------------------------------------------------------|--------------------------------------------------------------------------|
| S-19161AACA-M6T1U7 | 4.280 V                                                  | 4.080 V                                                | 2.800 V                                                     | 3.000 V                                                   | 100 mV                                                                   | -                                                                        |

**Table 2 (2 / 2)**

| Product Name       | Load Short-circuiting<br>Detection Voltage<br>[V <sub>SHORT</sub> ] | Charge Overcurrent<br>Detection Voltage<br>[V <sub>CIOV</sub> ] | Delay Time<br>Combination* <sup>1</sup> | 0 V Battery<br>Charge* <sup>2</sup> | Power-down<br>Function* <sup>3</sup> |
|--------------------|---------------------------------------------------------------------|-----------------------------------------------------------------|-----------------------------------------|-------------------------------------|--------------------------------------|
| S-19161AACA-M6T1U7 | 300 mV                                                              | -100 mV                                                         | (1)                                     | Inhibited                           | Unavailable                          |

\*1. Refer to **Table 3** about the details of the delay time combinations.

\*2. 0 V battery charge: Enabled, inhibited

\*3. Power-down function: Available, unavailable

**Remark** Please contact our sales representatives for products other than the above.

**Table 3**

| Delay Time Combination | Overcharge Detection Delay Time [t <sub>CU</sub> ] | Overdischarge Detection Delay Time [t <sub>DL</sub> ] | Discharge Overcurrent 1 Detection Delay Time [t <sub>DIOV1</sub> ] | Discharge Overcurrent 2 Detection Delay Time [t <sub>DIOV2</sub> ] | Load Short-circuiting Detection Delay Time [t <sub>SHORT</sub> ] | Charge Overcurrent Detection Delay Time [t <sub>CIOV</sub> ] |
|------------------------|----------------------------------------------------|-------------------------------------------------------|--------------------------------------------------------------------|--------------------------------------------------------------------|------------------------------------------------------------------|--------------------------------------------------------------|
| (1)                    | 1.0 s                                              | 128 ms                                                | 8 ms                                                               | -                                                                  | 280 μs                                                           | 8 ms                                                         |

**Remark** The delay times can be changed within the range listed in **Table 4**. For details, please contact our sales representatives.

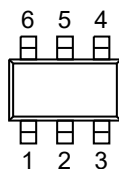
**Table 4**

| Delay Time                                   | Symbol             | Selection Range |        |        |       |        |        | Remark                        |
|----------------------------------------------|--------------------|-----------------|--------|--------|-------|--------|--------|-------------------------------|
| Overcharge detection delay time              | t <sub>CU</sub>    | 256 ms          | 512 ms | 1.0 s  | -     | -      | -      | Select a value from the left. |
| Overdischarge detection delay time           | t <sub>DL</sub>    | 32 ms           | 64 ms  | 128 ms | -     | -      | -      | Select a value from the left. |
| Discharge overcurrent 1 detection delay time | t <sub>DIOV1</sub> | 8 ms            | 16 ms  | 32 ms  | 64 ms | 128 ms | 256 ms | Select a value from the left. |
|                                              |                    | 512 ms          | 1.0 s  | 2.0 s  | 3.0 s | 3.75 s | 4.0 s  |                               |
| Discharge overcurrent 2 detection delay time | t <sub>DIOV2</sub> | 4 ms            | 8 ms   | 16 ms  | 32 ms | 64 ms  | 128 ms | Select a value from the left. |
| Load short-circuiting detection delay time   | t <sub>SHORT</sub> | 280 μs          | 530 μs | -      | -     | -      | -      | Select a value from the left. |
| Charge overcurrent detection delay time      | t <sub>CIOV</sub>  | 4 ms            | 8 ms   | 16 ms  | 32 ms | 64 ms  | 128 ms | Select a value from the left. |

## ■ Pin Configuration

### 1. SOT-23-6

Top view



**Figure 2**

**Table 5**

| Pin No. | Symbol           | Description                                                |
|---------|------------------|------------------------------------------------------------|
| 1       | DO               | Connection pin of discharge control FET gate (CMOS output) |
| 2       | CO               | Connection pin of charge control FET gate (CMOS output)    |
| 3       | VM               | Input pin for external negative voltage                    |
| 4       | NC <sup>*1</sup> | No connection                                              |
| 5       | VDD              | Input pin for positive power supply                        |
| 6       | VSS              | Input pin for negative power supply                        |

<sup>\*1</sup>. The NC pin is electrically open.  
 The NC pin can be connected to the VDD pin or the VSS pin.

## ■ Absolute Maximum Ratings

Table 6

(Ta = +25°C unless otherwise specified)

| Item                                      | Symbol           | Applied Pin | Absolute Maximum Rating                        | Unit |
|-------------------------------------------|------------------|-------------|------------------------------------------------|------|
| Input voltage between VDD pin and VSS pin | V <sub>DS</sub>  | VDD         | V <sub>SS</sub> - 0.3 to V <sub>SS</sub> + 6   | V    |
| VM pin input voltage                      | V <sub>VM</sub>  | VM          | V <sub>DD</sub> - 28 to V <sub>DD</sub> + 0.3  | V    |
| DO pin output voltage                     | V <sub>DO</sub>  | DO          | V <sub>SS</sub> - 0.3 to V <sub>DD</sub> + 0.3 | V    |
| CO pin output voltage                     | V <sub>CO</sub>  | CO          | V <sub>VM</sub> - 0.3 to V <sub>DD</sub> + 0.3 | V    |
| Operation ambient temperature             | T <sub>opr</sub> | -           | -40 to +125                                    | °C   |
| Storage temperature                       | T <sub>stg</sub> | -           | -55 to +125                                    | °C   |

**Caution** The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

## ■ Thermal Resistance Value

Table 7

| Item                                     | Symbol        | Condition |         | Min. | Typ. | Max. | Unit |
|------------------------------------------|---------------|-----------|---------|------|------|------|------|
| Junction-to-ambient thermal resistance*1 | $\theta_{JA}$ | SOT-23-6  | Board A | -    | 159  | -    | °C/W |
|                                          |               |           | Board B | -    | 124  | -    | °C/W |
|                                          |               |           | Board C | -    | -    | -    | °C/W |
|                                          |               |           | Board D | -    | -    | -    | °C/W |
|                                          |               |           | Board E | -    | -    | -    | °C/W |

\*1. Test environment: compliance with JEDEC STANDARD JESD51-2A

**Remark** Refer to "■ Power Dissipation" and "Test Board" for details.

## ■ Electrical Characteristics

### 1. Ta = +25°C

**Table 8**

(Ta = +25°C unless otherwise specified)

| Item                                          | Symbol             | Condition                                        | Min.                      | Typ.                   | Max.                      | Unit | Test Circuit |
|-----------------------------------------------|--------------------|--------------------------------------------------|---------------------------|------------------------|---------------------------|------|--------------|
| <b>Detection Voltage</b>                      |                    |                                                  |                           |                        |                           |      |              |
| Overcharge detection voltage                  | V <sub>CU</sub>    | -                                                | V <sub>CU</sub> - 0.015   | V <sub>CU</sub>        | V <sub>CU</sub> + 0.015   | V    | 1            |
| Overcharge release voltage                    | V <sub>CL</sub>    | V <sub>CL</sub> ≠ V <sub>CU</sub>                | V <sub>CL</sub> - 0.050   | V <sub>CL</sub>        | V <sub>CL</sub> + 0.050   | V    | 1            |
|                                               |                    | V <sub>CL</sub> = V <sub>CU</sub>                | V <sub>CL</sub> - 0.020   | V <sub>CL</sub>        | V <sub>CL</sub> + 0.015   | V    | 1            |
| Overdischarge detection voltage               | V <sub>DL</sub>    | -                                                | V <sub>DL</sub> - 0.050   | V <sub>DL</sub>        | V <sub>DL</sub> + 0.050   | V    | 2            |
| Overdischarge release voltage                 | V <sub>DU</sub>    | V <sub>DL</sub> ≠ V <sub>DU</sub>                | V <sub>DU</sub> - 0.075   | V <sub>DU</sub>        | V <sub>DU</sub> + 0.075   | V    | 2            |
|                                               |                    | V <sub>DL</sub> = V <sub>DU</sub>                | V <sub>DU</sub> - 0.050   | V <sub>DU</sub>        | V <sub>DU</sub> + 0.050   | V    | 2            |
| Discharge overcurrent 1 detection voltage     | V <sub>DIOV1</sub> | -                                                | V <sub>DIOV1</sub> - 1.5  | V <sub>DIOV1</sub>     | V <sub>DIOV1</sub> + 1.5  | mV   | 5            |
| Discharge overcurrent 2 detection voltage     | V <sub>DIOV2</sub> | -                                                | V <sub>DIOV2</sub> - 3    | V <sub>DIOV2</sub>     | V <sub>DIOV2</sub> + 3    | mV   | 2            |
| Load short-circuiting detection voltage       | V <sub>SHORT</sub> | 20 mV ≤ V <sub>SHORT</sub> ≤ 100 mV              | V <sub>SHORT</sub> - 5    | V <sub>SHORT</sub>     | V <sub>SHORT</sub> + 5    | mV   | 2            |
|                                               |                    | 101 mV ≤ V <sub>SHORT</sub> ≤ 300 mV             | V <sub>SHORT</sub> - 10   | V <sub>SHORT</sub>     | V <sub>SHORT</sub> + 10   | mV   | 2            |
| Charge overcurrent detection voltage          | V <sub>CIOV</sub>  | -                                                | V <sub>CIOV</sub> - 1.5   | V <sub>CIOV</sub>      | V <sub>CIOV</sub> + 1.5   | mV   | 2            |
| Discharge overcurrent release voltage         | V <sub>RIOV</sub>  | V <sub>DD</sub> = 3.4 V                          | V <sub>DD</sub> × 0.77    | V <sub>DD</sub> × 0.80 | V <sub>DD</sub> × 0.83    | V    | 5            |
| <b>0 V Battery Charge</b>                     |                    |                                                  |                           |                        |                           |      |              |
| 0 V battery charge starting charger voltage   | V <sub>0CHA</sub>  | 0 V battery charge enabled                       | 0.7                       | 1.1                    | 1.5                       | V    | 4            |
| 0 V battery charge inhibition battery voltage | V <sub>0INH</sub>  | 0 V battery charge inhibited                     | 1.0                       | 1.2                    | 1.4                       | V    | 2            |
| <b>Internal Resistance</b>                    |                    |                                                  |                           |                        |                           |      |              |
| Resistance between VDD pin and VM pin         | R <sub>VMD</sub>   | V <sub>DD</sub> = 1.8 V, V <sub>VM</sub> = 0 V   | 500                       | 1250                   | 2500                      | kΩ   | 3            |
| Resistance between VM pin and VSS pin         | R <sub>VMS</sub>   | V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 1.0 V | 5                         | 10                     | 15                        | kΩ   | 3            |
| <b>Input Voltage</b>                          |                    |                                                  |                           |                        |                           |      |              |
| Operation voltage between VDD pin and VSS pin | V <sub>DSOP1</sub> | -                                                | 1.5                       | -                      | 6.0                       | V    | -            |
| Operation voltage between VDD pin and VM pin  | V <sub>DSOP2</sub> | -                                                | 1.5                       | -                      | 28                        | V    | -            |
| <b>Input Current</b>                          |                    |                                                  |                           |                        |                           |      |              |
| Current consumption during operation          | I <sub>OPE</sub>   | V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 0 V   | -                         | 2.0                    | 4.0                       | μA   | 3            |
| Current consumption during power-down         | I <sub>PDN</sub>   | V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V        | -                         | -                      | 0.05                      | μA   | 3            |
| Current consumption during overdischarge      | I <sub>OPEd</sub>  | V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V        | -                         | -                      | 0.5                       | μA   | 3            |
| <b>Output Resistance</b>                      |                    |                                                  |                           |                        |                           |      |              |
| CO pin resistance "H"                         | R <sub>COH</sub>   | -                                                | 5                         | 10                     | 20                        | kΩ   | 4            |
| CO pin resistance "L"                         | R <sub>COL</sub>   | -                                                | 1.5                       | 3                      | 6                         | kΩ   | 4            |
| DO pin resistance "H"                         | R <sub>DOH</sub>   | -                                                | 5                         | 10                     | 20                        | kΩ   | 4            |
| DO pin resistance "L"                         | R <sub>DOL</sub>   | -                                                | 1                         | 2                      | 4                         | kΩ   | 4            |
| <b>Delay Time</b>                             |                    |                                                  |                           |                        |                           |      |              |
| Overcharge detection delay time               | t <sub>CU</sub>    | -                                                | t <sub>CU</sub> × 0.7     | t <sub>CU</sub>        | t <sub>CU</sub> × 1.3     | -    | 5            |
| Overdischarge detection delay time            | t <sub>DL</sub>    | -                                                | t <sub>DL</sub> × 0.7     | t <sub>DL</sub>        | t <sub>DL</sub> × 1.3     | -    | 5            |
| Discharge overcurrent 1 detection delay time  | t <sub>DIOV1</sub> | -                                                | t <sub>DIOV1</sub> × 0.75 | t <sub>DIOV1</sub>     | t <sub>DIOV1</sub> × 1.25 | -    | 5            |
| Discharge overcurrent 2 detection delay time  | t <sub>DIOV2</sub> | -                                                | t <sub>DIOV2</sub> × 0.7  | t <sub>DIOV2</sub>     | t <sub>DIOV2</sub> × 1.3  | -    | 5            |
| Load short-circuiting detection delay time    | t <sub>SHORT</sub> | -                                                | t <sub>SHORT</sub> × 0.7  | t <sub>SHORT</sub>     | t <sub>SHORT</sub> × 1.3  | -    | 5            |
| Charge overcurrent detection delay time       | t <sub>CIOV</sub>  | -                                                | t <sub>CIOV</sub> × 0.7   | t <sub>CIOV</sub>      | t <sub>CIOV</sub> × 1.3   | -    | 5            |

**2. Ta = -20°C to +60°C\*1**

**Table 9**

(Ta = -20°C to +60°C\*1 unless otherwise specified)

| Item                                          | Symbol             | Condition                                        | Min.                      | Typ.                   | Max.                      | Unit | Test Circuit |
|-----------------------------------------------|--------------------|--------------------------------------------------|---------------------------|------------------------|---------------------------|------|--------------|
| <b>Detection Voltage</b>                      |                    |                                                  |                           |                        |                           |      |              |
| Overcharge detection voltage                  | V <sub>CU</sub>    | -                                                | V <sub>CU</sub> - 0.020   | V <sub>CU</sub>        | V <sub>CU</sub> + 0.020   | V    | 1            |
| Overcharge release voltage                    | V <sub>CL</sub>    | V <sub>CL</sub> ≠ V <sub>CU</sub>                | V <sub>CL</sub> - 0.065   | V <sub>CL</sub>        | V <sub>CL</sub> + 0.057   | V    | 1            |
|                                               |                    | V <sub>CL</sub> = V <sub>CU</sub>                | V <sub>CL</sub> - 0.025   | V <sub>CL</sub>        | V <sub>CL</sub> + 0.020   | V    | 1            |
| Overdischarge detection voltage               | V <sub>DL</sub>    | -                                                | V <sub>DL</sub> - 0.060   | V <sub>DL</sub>        | V <sub>DL</sub> + 0.055   | V    | 2            |
| Overdischarge release voltage                 | V <sub>DU</sub>    | V <sub>DL</sub> ≠ V <sub>DU</sub>                | V <sub>DU</sub> - 0.085   | V <sub>DU</sub>        | V <sub>DU</sub> + 0.080   | V    | 2            |
|                                               |                    | V <sub>DL</sub> = V <sub>DU</sub>                | V <sub>DU</sub> - 0.060   | V <sub>DU</sub>        | V <sub>DU</sub> + 0.055   | V    | 2            |
| Discharge overcurrent 1 detection voltage     | V <sub>DIOV1</sub> | -                                                | V <sub>DIOV1</sub> - 2    | V <sub>DIOV1</sub>     | V <sub>DIOV1</sub> + 2    | mV   | 5            |
| Discharge overcurrent 2 detection voltage     | V <sub>DIOV2</sub> | -                                                | V <sub>DIOV2</sub> - 3    | V <sub>DIOV2</sub>     | V <sub>DIOV2</sub> + 3    | mV   | 2            |
| Load short-circuiting detection voltage       | V <sub>SHORT</sub> | 20 mV ≤ V <sub>SHORT</sub> ≤ 100 mV              | V <sub>SHORT</sub> - 5    | V <sub>SHORT</sub>     | V <sub>SHORT</sub> + 5    | mV   | 2            |
|                                               |                    | 101 mV ≤ V <sub>SHORT</sub> ≤ 300 mV             | V <sub>SHORT</sub> - 10   | V <sub>SHORT</sub>     | V <sub>SHORT</sub> + 10   | mV   | 2            |
| Charge overcurrent detection voltage          | V <sub>CIOV</sub>  | -                                                | V <sub>CIOV</sub> - 2     | V <sub>CIOV</sub>      | V <sub>CIOV</sub> + 2     | mV   | 2            |
| Discharge overcurrent release voltage         | V <sub>RIOV</sub>  | V <sub>DD</sub> = 3.4 V                          | V <sub>DD</sub> × 0.77    | V <sub>DD</sub> × 0.80 | V <sub>DD</sub> × 0.83    | V    | 5            |
| <b>0 V Battery Charge</b>                     |                    |                                                  |                           |                        |                           |      |              |
| 0 V battery charge starting charger voltage   | V <sub>0CHA</sub>  | 0 V battery charge enabled                       | 0.5                       | 1.1                    | 1.7                       | V    | 4            |
| 0 V battery charge inhibition battery voltage | V <sub>0INH</sub>  | 0 V battery charge inhibited                     | 1.0                       | 1.2                    | 1.4                       | V    | 2            |
| <b>Internal Resistance</b>                    |                    |                                                  |                           |                        |                           |      |              |
| Resistance between VDD pin and VM pin         | R <sub>VMD</sub>   | V <sub>DD</sub> = 1.8 V, V <sub>VM</sub> = 0 V   | 250                       | 1250                   | 3500                      | kΩ   | 3            |
| Resistance between VM pin and VSS pin         | R <sub>VMS</sub>   | V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 1.0 V | 3.5                       | 10                     | 20                        | kΩ   | 3            |
| <b>Input Voltage</b>                          |                    |                                                  |                           |                        |                           |      |              |
| Operation voltage between VDD pin and VSS pin | V <sub>DSOP1</sub> | -                                                | 1.5                       | -                      | 6.0                       | V    | -            |
| Operation voltage between VDD pin and VM pin  | V <sub>DSOP2</sub> | -                                                | 1.5                       | -                      | 28                        | V    | -            |
| <b>Input Current</b>                          |                    |                                                  |                           |                        |                           |      |              |
| Current consumption during operation          | I <sub>OP</sub>    | V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 0 V   | -                         | 2.0                    | 5.0                       | μA   | 3            |
| Current consumption during power-down         | I <sub>PDN</sub>   | V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V        | -                         | -                      | 0.1                       | μA   | 3            |
| Current consumption during overdischarge      | I <sub>OPED</sub>  | V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V        | -                         | -                      | 1.0                       | μA   | 3            |
| <b>Output Resistance</b>                      |                    |                                                  |                           |                        |                           |      |              |
| CO pin resistance "H"                         | R <sub>COH</sub>   | -                                                | 2.5                       | 10                     | 30                        | kΩ   | 4            |
| CO pin resistance "L"                         | R <sub>COL</sub>   | -                                                | 0.75                      | 3                      | 9                         | kΩ   | 4            |
| DO pin resistance "H"                         | R <sub>DOH</sub>   | -                                                | 2.5                       | 10                     | 30                        | kΩ   | 4            |
| DO pin resistance "L"                         | R <sub>DOL</sub>   | -                                                | 0.5                       | 2                      | 6                         | kΩ   | 4            |
| <b>Delay Time</b>                             |                    |                                                  |                           |                        |                           |      |              |
| Overcharge detection delay time               | t <sub>CU</sub>    | -                                                | t <sub>CU</sub> × 0.6     | t <sub>CU</sub>        | t <sub>CU</sub> × 1.4     | -    | 5            |
| Overdischarge detection delay time            | t <sub>DL</sub>    | -                                                | t <sub>DL</sub> × 0.6     | t <sub>DL</sub>        | t <sub>DL</sub> × 1.4     | -    | 5            |
| Discharge overcurrent 1 detection delay time  | t <sub>DIOV1</sub> | -                                                | t <sub>DIOV1</sub> × 0.65 | t <sub>DIOV1</sub>     | t <sub>DIOV1</sub> × 1.35 | -    | 5            |
| Discharge overcurrent 2 detection delay time  | t <sub>DIOV2</sub> | -                                                | t <sub>DIOV2</sub> × 0.6  | t <sub>DIOV2</sub>     | t <sub>DIOV2</sub> × 1.4  | -    | 5            |
| Load short-circuiting detection delay time    | t <sub>SHORT</sub> | -                                                | t <sub>SHORT</sub> × 0.6  | t <sub>SHORT</sub>     | t <sub>SHORT</sub> × 1.4  | -    | 5            |
| Charge overcurrent detection delay time       | t <sub>CIOV</sub>  | -                                                | t <sub>CIOV</sub> × 0.6   | t <sub>CIOV</sub>      | t <sub>CIOV</sub> × 1.4   | -    | 5            |

\*1. The specification for this temperature range is guaranteed by design, not tested in production.

**3. Ta = -40°C to +85°C\*1**

**Table 10**

(Ta = -40°C to +85°C\*1 unless otherwise specified)

| Item                                          | Symbol             | Condition                                        | Min.                     | Typ.                   | Max.                     | Unit | Test Circuit |
|-----------------------------------------------|--------------------|--------------------------------------------------|--------------------------|------------------------|--------------------------|------|--------------|
| <b>Detection Voltage</b>                      |                    |                                                  |                          |                        |                          |      |              |
| Overcharge detection voltage                  | V <sub>CU</sub>    | -                                                | V <sub>CU</sub> - 0.040  | V <sub>CU</sub>        | V <sub>CU</sub> + 0.028  | V    | 1            |
| Overcharge release voltage                    | V <sub>CL</sub>    | V <sub>CL</sub> ≠ V <sub>CU</sub>                | V <sub>CL</sub> - 0.075  | V <sub>CL</sub>        | V <sub>CL</sub> + 0.060  | V    | 1            |
|                                               |                    | V <sub>CL</sub> = V <sub>CU</sub>                | V <sub>CL</sub> - 0.045  | V <sub>CL</sub>        | V <sub>CL</sub> + 0.028  | V    | 1            |
| Overdischarge detection voltage               | V <sub>DL</sub>    | -                                                | V <sub>DL</sub> - 0.070  | V <sub>DL</sub>        | V <sub>DL</sub> + 0.060  | V    | 2            |
| Overdischarge release voltage                 | V <sub>DU</sub>    | V <sub>DL</sub> ≠ V <sub>DU</sub>                | V <sub>DU</sub> - 0.095  | V <sub>DU</sub>        | V <sub>DU</sub> + 0.085  | V    | 2            |
|                                               |                    | V <sub>DL</sub> = V <sub>DU</sub>                | V <sub>DU</sub> - 0.070  | V <sub>DU</sub>        | V <sub>DU</sub> + 0.060  | V    | 2            |
| Discharge overcurrent 1 detection voltage     | V <sub>DIOV1</sub> | -                                                | V <sub>DIOV1</sub> - 2   | V <sub>DIOV1</sub>     | V <sub>DIOV1</sub> + 2   | mV   | 5            |
| Discharge overcurrent 2 detection voltage     | V <sub>DIOV2</sub> | -                                                | V <sub>DIOV2</sub> - 3   | V <sub>DIOV2</sub>     | V <sub>DIOV2</sub> + 3   | mV   | 2            |
| Load short-circuiting detection voltage       | V <sub>SHORT</sub> | 20 mV ≤ V <sub>SHORT</sub> ≤ 100 mV              | V <sub>SHORT</sub> - 5   | V <sub>SHORT</sub>     | V <sub>SHORT</sub> + 5   | mV   | 2            |
|                                               |                    | 101 mV ≤ V <sub>SHORT</sub> ≤ 300 mV             | V <sub>SHORT</sub> - 10  | V <sub>SHORT</sub>     | V <sub>SHORT</sub> + 10  | mV   | 2            |
| Charge overcurrent detection voltage          | V <sub>CIOV</sub>  | -                                                | V <sub>CIOV</sub> - 2    | V <sub>CIOV</sub>      | V <sub>CIOV</sub> + 2    | mV   | 2            |
| Discharge overcurrent release voltage         | V <sub>RIOV</sub>  | V <sub>DD</sub> = 3.4 V                          | V <sub>DD</sub> × 0.77   | V <sub>DD</sub> × 0.80 | V <sub>DD</sub> × 0.83   | V    | 5            |
| <b>0 V Battery Charge</b>                     |                    |                                                  |                          |                        |                          |      |              |
| 0 V battery charge starting charger voltage   | V <sub>0CHA</sub>  | 0 V battery charge enabled                       | 0.5                      | 1.1                    | 1.7                      | V    | 4            |
| 0 V battery charge inhibition battery voltage | V <sub>0INH</sub>  | 0 V battery charge inhibited                     | 1.0                      | 1.2                    | 1.4                      | V    | 2            |
| <b>Internal Resistance</b>                    |                    |                                                  |                          |                        |                          |      |              |
| Resistance between VDD pin and VM pin         | R <sub>VMD</sub>   | V <sub>DD</sub> = 1.8 V, V <sub>VM</sub> = 0 V   | 250                      | 1250                   | 3500                     | kΩ   | 3            |
| Resistance between VM pin and VSS pin         | R <sub>VMS</sub>   | V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 1.0 V | 3.5                      | 10                     | 20                       | kΩ   | 3            |
| <b>Input Voltage</b>                          |                    |                                                  |                          |                        |                          |      |              |
| Operation voltage between VDD pin and VSS pin | V <sub>DSOP1</sub> | -                                                | 1.5                      | -                      | 6.0                      | V    | -            |
| Operation voltage between VDD pin and VM pin  | V <sub>DSOP2</sub> | -                                                | 1.5                      | -                      | 28                       | V    | -            |
| <b>Input Current</b>                          |                    |                                                  |                          |                        |                          |      |              |
| Current consumption during operation          | I <sub>OP</sub>    | V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 0 V   | -                        | 2.0                    | 5.0                      | μA   | 3            |
| Current consumption during power-down         | I <sub>PDN</sub>   | V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V        | -                        | -                      | 0.1                      | μA   | 3            |
| Current consumption during overdischarge      | I <sub>OPED</sub>  | V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V        | -                        | -                      | 1.0                      | μA   | 3            |
| <b>Output Resistance</b>                      |                    |                                                  |                          |                        |                          |      |              |
| CO pin resistance "H"                         | R <sub>COH</sub>   | -                                                | 2.5                      | 10                     | 30                       | kΩ   | 4            |
| CO pin resistance "L"                         | R <sub>COL</sub>   | -                                                | 0.75                     | 3                      | 9                        | kΩ   | 4            |
| DO pin resistance "H"                         | R <sub>DOH</sub>   | -                                                | 2.5                      | 10                     | 30                       | kΩ   | 4            |
| DO pin resistance "L"                         | R <sub>DOL</sub>   | -                                                | 0.5                      | 2                      | 6                        | kΩ   | 4            |
| <b>Delay Time</b>                             |                    |                                                  |                          |                        |                          |      |              |
| Overcharge detection delay time               | t <sub>CU</sub>    | -                                                | t <sub>CU</sub> × 0.4    | t <sub>CU</sub>        | t <sub>CU</sub> × 1.6    | -    | 5            |
| Overdischarge detection delay time            | t <sub>DL</sub>    | -                                                | t <sub>DL</sub> × 0.4    | t <sub>DL</sub>        | t <sub>DL</sub> × 1.6    | -    | 5            |
| Discharge overcurrent 1 detection delay time  | t <sub>DIOV1</sub> | -                                                | t <sub>DIOV1</sub> × 0.4 | t <sub>DIOV1</sub>     | t <sub>DIOV1</sub> × 1.6 | -    | 5            |
| Discharge overcurrent 2 detection delay time  | t <sub>DIOV2</sub> | -                                                | t <sub>DIOV2</sub> × 0.4 | t <sub>DIOV2</sub>     | t <sub>DIOV2</sub> × 1.6 | -    | 5            |
| Load short-circuiting detection delay time    | t <sub>SHORT</sub> | -                                                | t <sub>SHORT</sub> × 0.4 | t <sub>SHORT</sub>     | t <sub>SHORT</sub> × 1.6 | -    | 5            |
| Charge overcurrent detection delay time       | t <sub>CIOV</sub>  | -                                                | t <sub>CIOV</sub> × 0.4  | t <sub>CIOV</sub>      | t <sub>CIOV</sub> × 1.6  | -    | 5            |

\*1. The specification for this temperature range is guaranteed by design, not tested in production.

**4. Ta = -40°C to +105°C\***

**Table 11**

(Ta = -40°C to +105°C\* unless otherwise specified)

| Item                                          | Symbol             | Condition                                        | Min.                      | Typ.                   | Max.                      | Unit | Test Circuit |
|-----------------------------------------------|--------------------|--------------------------------------------------|---------------------------|------------------------|---------------------------|------|--------------|
| <b>Detection Voltage</b>                      |                    |                                                  |                           |                        |                           |      |              |
| Overcharge detection voltage                  | V <sub>CU</sub>    | -                                                | V <sub>CU</sub> - 0.042   | V <sub>CU</sub>        | V <sub>CU</sub> + 0.030   | V    | 1            |
| Overcharge release voltage                    | V <sub>CL</sub>    | V <sub>CL</sub> ≠ V <sub>CU</sub>                | V <sub>CL</sub> - 0.077   | V <sub>CL</sub>        | V <sub>CL</sub> + 0.060   | V    | 1            |
|                                               |                    | V <sub>CL</sub> = V <sub>CU</sub>                | V <sub>CL</sub> - 0.047   | V <sub>CL</sub>        | V <sub>CL</sub> + 0.030   | V    | 1            |
| Overdischarge detection voltage               | V <sub>DL</sub>    | -                                                | V <sub>DL</sub> - 0.075   | V <sub>DL</sub>        | V <sub>DL</sub> + 0.060   | V    | 2            |
| Overdischarge release voltage                 | V <sub>DU</sub>    | V <sub>DL</sub> ≠ V <sub>DU</sub>                | V <sub>DU</sub> - 0.100   | V <sub>DU</sub>        | V <sub>DU</sub> + 0.085   | V    | 2            |
|                                               |                    | V <sub>DL</sub> = V <sub>DU</sub>                | V <sub>DU</sub> - 0.075   | V <sub>DU</sub>        | V <sub>DU</sub> + 0.060   | V    | 2            |
| Discharge overcurrent 1 detection voltage     | V <sub>DIOV1</sub> | -                                                | V <sub>DIOV1</sub> - 2.5  | V <sub>DIOV1</sub>     | V <sub>DIOV1</sub> + 2.5  | mV   | 5            |
| Discharge overcurrent 2 detection voltage     | V <sub>DIOV2</sub> | -                                                | V <sub>DIOV2</sub> - 4.5  | V <sub>DIOV2</sub>     | V <sub>DIOV2</sub> + 4.5  | mV   | 2            |
| Load short-circuiting detection voltage       | V <sub>SHORT</sub> | 20 mV ≤ V <sub>SHORT</sub> ≤ 100 mV              | V <sub>SHORT</sub> - 6    | V <sub>SHORT</sub>     | V <sub>SHORT</sub> + 6    | mV   | 2            |
|                                               |                    | 101 mV ≤ V <sub>SHORT</sub> ≤ 300 mV             | V <sub>SHORT</sub> - 10   | V <sub>SHORT</sub>     | V <sub>SHORT</sub> + 10   | mV   | 2            |
| Charge overcurrent detection voltage          | V <sub>CIOV</sub>  | -                                                | V <sub>CIOV</sub> - 2.5   | V <sub>CIOV</sub>      | V <sub>CIOV</sub> + 2.5   | mV   | 2            |
| Discharge overcurrent release voltage         | V <sub>RIOV</sub>  | V <sub>DD</sub> = 3.4 V                          | V <sub>DD</sub> × 0.77    | V <sub>DD</sub> × 0.80 | V <sub>DD</sub> × 0.83    | V    | 5            |
| <b>0 V Battery Charge</b>                     |                    |                                                  |                           |                        |                           |      |              |
| 0 V battery charge starting charger voltage   | V <sub>0CHA</sub>  | 0 V battery charge enabled                       | 0.4                       | 1.1                    | 1.8                       | V    | 4            |
| 0 V battery charge inhibition battery voltage | V <sub>0INH</sub>  | 0 V battery charge inhibited                     | 1.0                       | 1.2                    | 1.4                       | V    | 2            |
| <b>Internal Resistance</b>                    |                    |                                                  |                           |                        |                           |      |              |
| Resistance between VDD pin and VM pin         | R <sub>VMD</sub>   | V <sub>DD</sub> = 1.8 V, V <sub>VM</sub> = 0 V   | 250                       | 1250                   | 3500                      | kΩ   | 3            |
| Resistance between VM pin and VSS pin         | R <sub>VMS</sub>   | V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 1.0 V | 3.5                       | 10                     | 20                        | kΩ   | 3            |
| <b>Input Voltage</b>                          |                    |                                                  |                           |                        |                           |      |              |
| Operation voltage between VDD pin and VSS pin | V <sub>DSOP1</sub> | -                                                | 1.5                       | -                      | 6.0                       | V    | -            |
| Operation voltage between VDD pin and VM pin  | V <sub>DSOP2</sub> | -                                                | 1.5                       | -                      | 28                        | V    | -            |
| <b>Input Current</b>                          |                    |                                                  |                           |                        |                           |      |              |
| Current consumption during operation          | I <sub>OP</sub>    | V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 0 V   | -                         | 2.0                    | 5.0                       | μA   | 3            |
| Current consumption during power-down         | I <sub>PDN</sub>   | V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V        | -                         | -                      | 0.5                       | μA   | 3            |
| Current consumption during overdischarge      | I <sub>OPED</sub>  | V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V        | -                         | -                      | 1.0                       | μA   | 3            |
| <b>Output Resistance</b>                      |                    |                                                  |                           |                        |                           |      |              |
| CO pin resistance "H"                         | R <sub>COH</sub>   | -                                                | 2.5                       | 10                     | 30                        | kΩ   | 4            |
| CO pin resistance "L"                         | R <sub>COL</sub>   | -                                                | 0.75                      | 3                      | 9                         | kΩ   | 4            |
| DO pin resistance "H"                         | R <sub>DOH</sub>   | -                                                | 2.5                       | 10                     | 30                        | kΩ   | 4            |
| DO pin resistance "L"                         | R <sub>DOL</sub>   | -                                                | 0.5                       | 2                      | 6                         | kΩ   | 4            |
| <b>Delay Time</b>                             |                    |                                                  |                           |                        |                           |      |              |
| Overcharge detection delay time               | t <sub>CU</sub>    | -                                                | t <sub>CU</sub> × 0.35    | t <sub>CU</sub>        | t <sub>CU</sub> × 1.65    | -    | 5            |
| Overdischarge detection delay time            | t <sub>DL</sub>    | -                                                | t <sub>DL</sub> × 0.35    | t <sub>DL</sub>        | t <sub>DL</sub> × 1.65    | -    | 5            |
| Discharge overcurrent 1 detection delay time  | t <sub>DIOV1</sub> | -                                                | t <sub>DIOV1</sub> × 0.35 | t <sub>DIOV1</sub>     | t <sub>DIOV1</sub> × 1.65 | -    | 5            |
| Discharge overcurrent 2 detection delay time  | t <sub>DIOV2</sub> | -                                                | t <sub>DIOV2</sub> × 0.35 | t <sub>DIOV2</sub>     | t <sub>DIOV2</sub> × 1.65 | -    | 5            |
| Load short-circuiting detection delay time    | t <sub>SHORT</sub> | -                                                | t <sub>SHORT</sub> × 0.35 | t <sub>SHORT</sub>     | t <sub>SHORT</sub> × 1.65 | -    | 5            |
| Charge overcurrent detection delay time       | t <sub>CIOV</sub>  | -                                                | t <sub>CIOV</sub> × 0.35  | t <sub>CIOV</sub>      | t <sub>CIOV</sub> × 1.65  | -    | 5            |

\*1. The specification for this temperature range is guaranteed by design, not tested in production.

**5. Ta = -40°C to +125°C\***

**Table 12**

(Ta = -40°C to +125°C\*1 unless otherwise specified)

| Item                                          | Symbol             | Condition                                        | Min.                     | Typ.                   | Max.                     | Unit | Test Circuit |
|-----------------------------------------------|--------------------|--------------------------------------------------|--------------------------|------------------------|--------------------------|------|--------------|
| <b>Detection Voltage</b>                      |                    |                                                  |                          |                        |                          |      |              |
| Overcharge detection voltage                  | V <sub>CU</sub>    | -                                                | V <sub>CU</sub> - 0.045  | V <sub>CU</sub>        | V <sub>CU</sub> + 0.030  | V    | 1            |
| Overcharge release voltage                    | V <sub>CL</sub>    | V <sub>CL</sub> ≠ V <sub>CU</sub>                | V <sub>CL</sub> - 0.080  | V <sub>CL</sub>        | V <sub>CL</sub> + 0.060  | V    | 1            |
|                                               |                    | V <sub>CL</sub> = V <sub>CU</sub>                | V <sub>CL</sub> - 0.050  | V <sub>CL</sub>        | V <sub>CL</sub> + 0.030  | V    | 1            |
| Overdischarge detection voltage               | V <sub>DL</sub>    | -                                                | V <sub>DL</sub> - 0.080  | V <sub>DL</sub>        | V <sub>DL</sub> + 0.060  | V    | 2            |
| Overdischarge release voltage                 | V <sub>DU</sub>    | V <sub>DL</sub> ≠ V <sub>DU</sub>                | V <sub>DU</sub> - 0.105  | V <sub>DU</sub>        | V <sub>DU</sub> + 0.085  | V    | 2            |
|                                               |                    | V <sub>DL</sub> = V <sub>DU</sub>                | V <sub>DU</sub> - 0.080  | V <sub>DU</sub>        | V <sub>DU</sub> + 0.060  | V    | 2            |
| Discharge overcurrent 1 detection voltage     | V <sub>DIOV1</sub> | -                                                | V <sub>DIOV1</sub> - 2.5 | V <sub>DIOV1</sub>     | V <sub>DIOV1</sub> + 4   | mV   | 5            |
| Discharge overcurrent 2 detection voltage     | V <sub>DIOV2</sub> | -                                                | V <sub>DIOV2</sub> - 4.5 | V <sub>DIOV2</sub>     | V <sub>DIOV2</sub> + 4.5 | mV   | 2            |
| Load short-circuiting detection voltage       | V <sub>SHORT</sub> | 20 mV ≤ V <sub>SHORT</sub> ≤ 100 mV              | V <sub>SHORT</sub> - 6   | V <sub>SHORT</sub>     | V <sub>SHORT</sub> + 6   | mV   | 2            |
|                                               |                    | 101 mV ≤ V <sub>SHORT</sub> ≤ 300 mV             | V <sub>SHORT</sub> - 10  | V <sub>SHORT</sub>     | V <sub>SHORT</sub> + 10  | mV   | 2            |
| Charge overcurrent detection voltage          | V <sub>CIOV</sub>  | -                                                | V <sub>CIOV</sub> - 4    | V <sub>CIOV</sub>      | V <sub>CIOV</sub> + 2.5  | mV   | 2            |
| Discharge overcurrent release voltage         | V <sub>RIOV</sub>  | V <sub>DD</sub> = 3.4 V                          | V <sub>DD</sub> × 0.77   | V <sub>DD</sub> × 0.80 | V <sub>DD</sub> × 0.83   | V    | 5            |
| <b>0 V Battery Charge</b>                     |                    |                                                  |                          |                        |                          |      |              |
| 0 V battery charge starting charger voltage   | V <sub>0CHA</sub>  | 0 V battery charge enabled                       | 0.4                      | 1.1                    | 1.8                      | V    | 4            |
| 0 V battery charge inhibition battery voltage | V <sub>0INH</sub>  | 0 V battery charge inhibited                     | 1.0                      | 1.2                    | 1.4                      | V    | 2            |
| <b>Internal Resistance</b>                    |                    |                                                  |                          |                        |                          |      |              |
| Resistance between VDD pin and VM pin         | R <sub>VMD</sub>   | V <sub>DD</sub> = 1.8 V, V <sub>VM</sub> = 0 V   | 250                      | 1250                   | 3500                     | kΩ   | 3            |
| Resistance between VM pin and VSS pin         | R <sub>VMS</sub>   | V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 1.0 V | 3.5                      | 10                     | 20                       | kΩ   | 3            |
| <b>Input Voltage</b>                          |                    |                                                  |                          |                        |                          |      |              |
| Operation voltage between VDD pin and VSS pin | V <sub>DSOP1</sub> | -                                                | 1.5                      | -                      | 6.0                      | V    | -            |
| Operation voltage between VDD pin and VM pin  | V <sub>DSOP2</sub> | -                                                | 1.5                      | -                      | 28                       | V    | -            |
| <b>Input Current</b>                          |                    |                                                  |                          |                        |                          |      |              |
| Current consumption during operation          | I <sub>OP</sub>    | V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 0 V   | -                        | 2.0                    | 5.0                      | μA   | 3            |
| Current consumption during power-down         | I <sub>PDN</sub>   | V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V        | -                        | -                      | 0.5                      | μA   | 3            |
| Current consumption during overdischarge      | I <sub>OPED</sub>  | V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V        | -                        | -                      | 1.0                      | μA   | 3            |
| <b>Output Resistance</b>                      |                    |                                                  |                          |                        |                          |      |              |
| CO pin resistance "H"                         | R <sub>COH</sub>   | -                                                | 2.5                      | 10                     | 30                       | kΩ   | 4            |
| CO pin resistance "L"                         | R <sub>COL</sub>   | -                                                | 0.75                     | 3                      | 9                        | kΩ   | 4            |
| DO pin resistance "H"                         | R <sub>DOH</sub>   | -                                                | 2.5                      | 10                     | 30                       | kΩ   | 4            |
| DO pin resistance "L"                         | R <sub>DOL</sub>   | -                                                | 0.5                      | 2                      | 6                        | kΩ   | 4            |
| <b>Delay Time</b>                             |                    |                                                  |                          |                        |                          |      |              |
| Overcharge detection delay time               | t <sub>CU</sub>    | -                                                | t <sub>CU</sub> × 0.3    | t <sub>CU</sub>        | t <sub>CU</sub> × 1.7    | -    | 5            |
| Overdischarge detection delay time            | t <sub>DL</sub>    | -                                                | t <sub>DL</sub> × 0.3    | t <sub>DL</sub>        | t <sub>DL</sub> × 1.7    | -    | 5            |
| Discharge overcurrent 1 detection delay time  | t <sub>DIOV1</sub> | -                                                | t <sub>DIOV1</sub> × 0.3 | t <sub>DIOV1</sub>     | t <sub>DIOV1</sub> × 1.7 | -    | 5            |
| Discharge overcurrent 2 detection delay time  | t <sub>DIOV2</sub> | -                                                | t <sub>DIOV2</sub> × 0.3 | t <sub>DIOV2</sub>     | t <sub>DIOV2</sub> × 1.7 | -    | 5            |
| Load short-circuiting detection delay time    | t <sub>SHORT</sub> | -                                                | t <sub>SHORT</sub> × 0.3 | t <sub>SHORT</sub>     | t <sub>SHORT</sub> × 1.7 | -    | 5            |
| Charge overcurrent detection delay time       | t <sub>CIOV</sub>  | -                                                | t <sub>CIOV</sub> × 0.3  | t <sub>CIOV</sub>      | t <sub>CIOV</sub> × 1.7  | -    | 5            |

\*1. The specification for this temperature range is guaranteed by design, not tested in production.

## ■ Test Circuits

**Caution** Unless otherwise specified, the output voltage levels "H" and "L" at CO pin ( $V_{CO}$ ) and DO pin ( $V_{DO}$ ) are judged by the threshold voltage (1.0 V) of the N-channel FET. Judge the CO pin level with respect to  $V_{VM}$  and the DO pin level with respect to  $V_{SS}$ .

### 1. Overcharge detection voltage, overcharge release voltage (Test circuit 1)

#### 1.1 $V_{CU} \neq V_{CL}$ (Product in which overcharge release voltage differs from overcharge detection voltage)

Overcharge detection voltage ( $V_{CU}$ ) is defined as the voltage  $V_1$  at which  $V_{CO}$  goes from "H" to "L" when the voltage  $V_1$  is gradually increased after setting  $V_1 = 3.4$  V,  $V_2 = 0$  V. Overcharge release voltage ( $V_{CL}$ ) is defined as the voltage  $V_1$  at which  $V_{CO}$  goes from "L" to "H" when the voltage  $V_1$  is then gradually decreased. Overcharge hysteresis voltage ( $V_{HC}$ ) is defined as the difference between  $V_{CU}$  and  $V_{CL}$ .

#### 1.2 $V_{CU} = V_{CL}$ (Product in which overcharge release voltage is the same as overcharge detection voltage)

Overcharge detection voltage ( $V_{CU}$ ) is defined as the voltage  $V_1$  at which  $V_{CO}$  goes from "H" to "L" when the voltage  $V_1$  is gradually increased after setting  $V_1 = 3.4$  V,  $V_2 = 0$  V. Overcharge release voltage ( $V_{CL}$ ) is defined as the voltage  $V_1$  at which  $V_{CO}$  goes from "L" to "H" when setting  $V_2 = 0.4$  V and when the voltage  $V_1$  is then gradually decreased. Overcharge hysteresis voltage ( $V_{HC}$ ) is defined as the difference between  $V_{CU}$  and  $V_{CL}$ .

### 2. Overdischarge detection voltage, overdischarge release voltage (Test circuit 2)

Overdischarge detection voltage ( $V_{DL}$ ) is defined as the voltage  $V_1$  at which  $V_{DO}$  goes from "H" to "L" when the voltage  $V_1$  is gradually decreased after setting  $V_1 = 3.4$  V,  $V_2 = 0$  V. Overdischarge release voltage ( $V_{DU}$ ) is defined as the voltage  $V_1$  at which  $V_{DO}$  goes from "L" to "H" when setting  $V_2 = 0.01$  V and when the voltage  $V_1$  is then gradually increased. Overdischarge hysteresis voltage ( $V_{HD}$ ) is defined as the difference between  $V_{DU}$  and  $V_{DL}$ .

### 3. Discharge overcurrent 1 detection voltage, discharge overcurrent release voltage (Test circuit 5)

Discharge overcurrent 1 detection voltage ( $V_{DIOV1}$ ) is defined as the voltage  $V_2$  at which delay time from when  $V_2$  is increased after setting  $V_1 = 3.4$  V,  $V_2 = 0$  V to when  $V_{DO}$  goes from "H" to "L" is discharge overcurrent 1 detection delay time ( $t_{DIOV1}$ ). Discharge overcurrent release voltage ( $V_{RIOV}$ ) is defined as the voltage  $V_2$  at which  $V_{DO}$  goes from "L" to "H" when setting  $V_2 = 3.4$  V and when the voltage  $V_2$  is then gradually decreased.

When the voltage  $V_2$  falls below  $V_{RIOV}$ ,  $V_{DO}$  will go to "H" after 1.0 ms typ. and maintain "H" during load short-circuiting detection delay time ( $t_{SHORT}$ ).

### 4. Discharge overcurrent 2 detection voltage (Test circuit 2)

Discharge overcurrent 2 detection voltage ( $V_{DIOV2}$ ) is defined as the voltage  $V_2$  at which delay time from when  $V_2$  is increased after setting  $V_1 = 3.4$  V,  $V_2 = 0$  V to when  $V_{DO}$  goes from "H" to "L" is discharge overcurrent 2 detection delay time ( $t_{DIOV2}$ ).

### 5. Load short-circuiting detection voltage (Test circuit 2)

Load short-circuiting detection voltage ( $V_{SHORT}$ ) is defined as the voltage  $V_2$  at which delay time from when  $V_2$  is increased after setting  $V_1 = 3.4$  V,  $V_2 = 0$  V to when  $V_{DO}$  goes from "H" to "L" is  $t_{SHORT}$ .

**6. Charge overcurrent detection voltage**  
**(Test circuit 2)**

Charge overcurrent detection voltage ( $V_{CIOV}$ ) is defined as the voltage  $V_2$  at which delay time from when  $V_2$  is decreased after setting  $V_1 = 3.4\text{ V}$ ,  $V_2 = 0\text{ V}$  to when  $V_{CO}$  goes from "H" to "L" is charge overcurrent detection delay time ( $t_{CIOV}$ ).

**7. Current consumption during operation**  
**(Test circuit 3)**

The current consumption during operation ( $I_{OPE}$ ) is the current that flows through the VDD pin ( $I_{DD}$ ) under the set conditions of  $V_1 = 3.4\text{ V}$ ,  $V_2 = 0\text{ V}$ .

**8. Current consumption during power-down, current consumption during overdischarge**  
**(Test circuit 3)**

**8.1 With power-down function**

The current consumption during power-down ( $I_{PDN}$ ) is  $I_{DD}$  under the set conditions of  $V_1 = V_2 = 1.5\text{ V}$ .

**8.2 Without power-down function**

The current consumption during overdischarge ( $I_{OPED}$ ) is  $I_{DD}$  under the set conditions of  $V_1 = V_2 = 1.5\text{ V}$ .

**9. Resistance between VDD pin and VM pin**  
**(Test circuit 3)**

$R_{VMD}$  is the resistance between VDD pin and VM pin under the set conditions of  $V_1 = 1.8\text{ V}$ ,  $V_2 = 0\text{ V}$ .

**10. Resistance between VM pin and VSS pin**  
**(Test circuit 3)**

$R_{VMS}$  is the resistance between VM pin and VSS pin under the set conditions of  $V_1 = 3.4\text{ V}$ ,  $V_2 = 1.0\text{ V}$ .

**11. CO pin resistance "H"**  
**(Test circuit 4)**

The CO pin resistance "H" ( $R_{COH}$ ) is the resistance between VDD pin and CO pin under the set conditions of  $V_1 = 3.4\text{ V}$ ,  $V_2 = 0\text{ V}$ ,  $V_3 = 3.0\text{ V}$ .

**12. CO pin resistance "L"**  
**(Test circuit 4)**

The CO pin resistance "L" ( $R_{COL}$ ) is the resistance between VM pin and CO pin under the set conditions of  $V_1 = 4.7\text{ V}$ ,  $V_2 = 0\text{ V}$ ,  $V_3 = 0.4\text{ V}$ .

**13. DO pin resistance "H"**  
**(Test circuit 4)**

The DO pin resistance "H" ( $R_{DOH}$ ) is the resistance between VDD pin and DO pin under the set conditions of  $V_1 = 3.4\text{ V}$ ,  $V_2 = 0\text{ V}$ ,  $V_4 = 3.0\text{ V}$ .

**14. DO pin resistance "L"**  
**(Test circuit 4)**

The DO pin resistance "L" ( $R_{DOL}$ ) is the resistance between VSS pin and DO pin under the set conditions of  $V_1 = 1.8\text{ V}$ ,  $V_2 = 0\text{ V}$ ,  $V_4 = 0.4\text{ V}$ .

**15. Overcharge detection delay time**  
**(Test circuit 5)**

After setting  $V_1 = 3.4\text{ V}$ ,  $V_2 = 0\text{ V}$ , the voltage  $V_1$  is increased. The time interval from when the voltage  $V_1$  exceeds  $V_{CU}$  until  $V_{CO}$  goes to "L" is the overcharge detection delay time ( $t_{CU}$ ).

**16. Overdischarge detection delay time**  
**(Test circuit 5)**

After setting  $V_1 = 3.4\text{ V}$ ,  $V_2 = 0\text{ V}$ , the voltage  $V_1$  is decreased. The time interval from when the voltage  $V_1$  falls below  $V_{DL}$  until  $V_{DO}$  goes to "L" is the overdischarge detection delay time ( $t_{DL}$ ).

**17. Discharge overcurrent 1 detection delay time**  
**(Test circuit 5)**

After setting  $V_1 = 3.4\text{ V}$ ,  $V_2 = 0\text{ V}$ , the voltage  $V_2$  is increased. The time interval from when the voltage  $V_2$  exceeds  $V_{DIOV1}$  until  $V_{DO}$  goes to "L" is the discharge overcurrent 1 detection delay time ( $t_{DIOV1}$ ).

**18. Discharge overcurrent 2 detection delay time**  
**(Test circuit 5)**

After setting  $V_1 = 3.4\text{ V}$ ,  $V_2 = 0\text{ V}$ , the voltage  $V_2$  is increased. The time interval from when the voltage  $V_2$  exceeds  $V_{DIOV2}$  until  $V_{DO}$  goes to "L" is the discharge overcurrent 2 detection delay time ( $t_{DIOV2}$ ).

**19. Load short-circuiting detection delay time**  
**(Test circuit 5)**

After setting  $V_1 = 3.4\text{ V}$ ,  $V_2 = 0\text{ V}$ , the voltage  $V_2$  is increased. The time interval from when the voltage  $V_2$  exceeds  $V_{SHORT}$  until  $V_{DO}$  goes to "L" is the load short-circuiting detection delay time ( $t_{SHORT}$ ).

**20. Charge overcurrent detection delay time**  
**(Test circuit 5)**

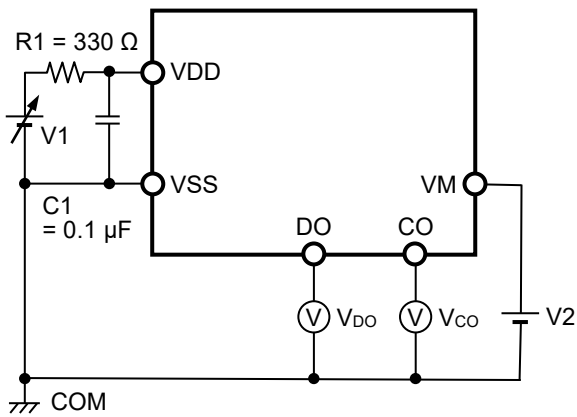
After setting  $V_1 = 3.4\text{ V}$ ,  $V_2 = 0\text{ V}$ , the voltage  $V_2$  is decreased. The time interval from when the voltage  $V_2$  falls below  $V_{CIOV}$  until  $V_{CO}$  goes to "L" is the charge overcurrent detection delay time ( $t_{CIOV}$ ).

**21. 0 V battery charge starting charger voltage (0 V battery charge enabled)**  
**(Test circuit 4)**

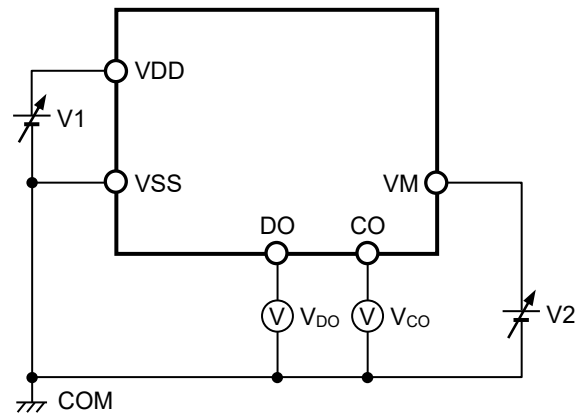
The 0 V battery charge starting charger voltage ( $V_{0CHA}$ ) is defined as the absolute value of voltage  $V_2$  at which the current flowing through the CO pin ( $I_{CO}$ ) exceeds  $1.0\text{ }\mu\text{A}$  when the voltage  $V_2$  is gradually decreased after setting  $V_1 = 0\text{ V}$ ,  $V_2 = V_3 = -0.5\text{ V}$ .

**22. 0 V battery charge inhibition battery voltage (0 V battery charge inhibited)**  
**(Test circuit 2)**

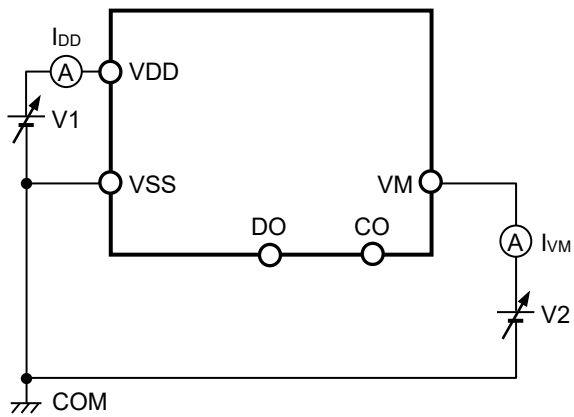
The 0 V battery charge inhibition battery voltage ( $V_{0INH}$ ) is defined as the voltage  $V_1$  at which  $V_{CO}$  goes to "L" ( $V_{CO} = V_{VM}$ ) when the voltage  $V_1$  is gradually decreased after setting  $V_1 = 1.8\text{ V}$ ,  $V_2 = -2.0\text{ V}$ .



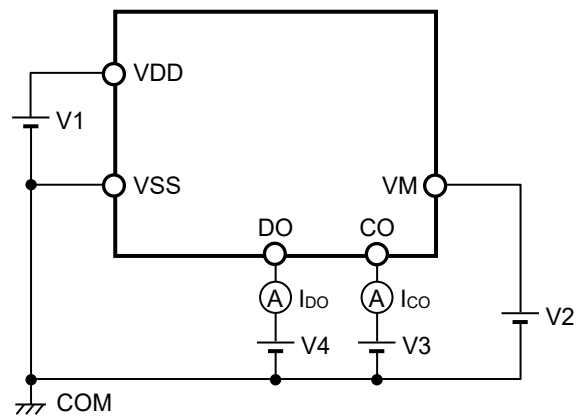
**Figure 3 Test Circuit 1**



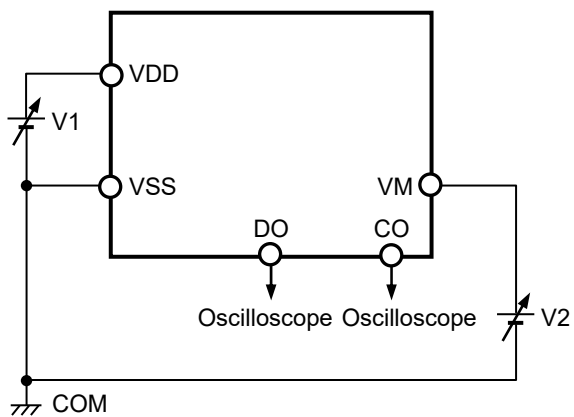
**Figure 4 Test Circuit 2**



**Figure 5 Test Circuit 3**



**Figure 6 Test Circuit 4**



**Figure 7 Test Circuit 5**

## ■ Operation

**Remark** Refer to "■ Battery Protection IC Connection Example".

### 1. Normal status

This IC monitors the voltage of the battery connected between VDD pin and VSS pin, and the voltage between VM pin and VSS pin to control charging and discharging. When the battery voltage is in the range from overdischarge detection voltage ( $V_{DL}$ ) to overcharge detection voltage ( $V_{CU}$ ), the VM pin voltage is in the range from charge overcurrent detection voltage ( $V_{CIOV}$ ) to discharge overcurrent 1 detection voltage ( $V_{DIOV1}$ ), both charge and discharge control FETs are turned on. This status is called the normal status, and in this condition charging and discharging can be carried out freely.

The resistance between VDD pin and VM pin ( $R_{VMD}$ ), and the resistance between VM pin and VSS pin ( $R_{VMS}$ ) are not connected in the normal status.

**Caution** After the battery is connected, discharging may not be carried out. In this case, this IC returns to the normal status by connecting a charger.

## 2. Overcharge status

### 2.1 $V_{CL} \neq V_{CU}$ (Product in which overcharge release voltage differs from overcharge detection voltage)

When the battery voltage becomes higher than  $V_{CU}$  during charging in the normal status and the condition continues for the overcharge detection delay time ( $t_{CU}$ ) or longer, the charge control FET is turned off and charging is stopped. This status is called the overcharge status.

The overcharge status is released in the following two cases.

- (1) In the case that the VM pin voltage is lower than 0.35 V typ., this IC releases the overcharge status when the battery voltage falls below overcharge release voltage ( $V_{CL}$ ).
- (2) In the case that the VM pin voltage is equal to or higher than 0.35 V typ., this IC releases the overcharge status when the battery voltage falls below  $V_{CU}$ .

When the discharge is started by connecting a load after the overcharge detection, the VM pin voltage rises by the  $V_f$  voltage of the internal parasitic diode than the VSS pin voltage, because the discharge current flows through the parasitic diode in the charge control FET. If this VM pin voltage is equal to or higher than 0.35 V typ., this IC releases the overcharge status when the battery voltage is equal to or lower than  $V_{CU}$ .

**Caution** If the battery is charged to a voltage higher than  $V_{CU}$  and the battery voltage does not fall below  $V_{CU}$  even when a heavy load is connected, discharge overcurrent detection and load short-circuiting detection do not function until the battery voltage falls below  $V_{CU}$ . Since an actual battery has an internal impedance of tens of mΩ, the battery voltage drops immediately after a heavy load that causes overcurrent is connected, and discharge overcurrent detection and load short-circuiting detection function.

### 2.2 $V_{CL} = V_{CU}$ (Product in which overcharge release voltage is the same as overcharge detection voltage)

When the battery voltage becomes higher than  $V_{CU}$  during charging in the normal status and the condition continues for  $t_{CU}$  or longer, the charge control FET is turned off and charging is stopped. This status is called the overcharge status.

In the case that the VM pin voltage is equal to or higher than 0.35 V typ. and the battery voltage falls below  $V_{CU}$ , this IC releases the overcharge status.

When the discharge is started by connecting a load after the overcharge detection, the VM pin voltage rises by the  $V_f$  voltage of the internal parasitic diode than the VSS pin voltage, because the discharge current flows through the parasitic diode in the charge control FET. If this VM pin voltage is equal to or higher than 0.35 V typ., this IC releases the overcharge status when the battery voltage is equal to or lower than  $V_{CU}$ .

- Caution**
1. If the battery is charged to a voltage higher than  $V_{CU}$  and the battery voltage does not fall below  $V_{CU}$  even when a heavy load is connected, discharge overcurrent detection and load short-circuiting detection do not function until the battery voltage falls below  $V_{CU}$ . Since an actual battery has an internal impedance of tens of mΩ, the battery voltage drops immediately after a heavy load that causes overcurrent is connected, and discharge overcurrent detection and load short-circuiting detection function.
  2. When a charger is connected after overcharge detection, the overcharge status is not released even if the battery voltage is below  $V_{CL}$ . The overcharge status is released when the discharge current flows and the VM pin voltage goes over 0.35 V typ. by removing the charger.

### 3. Overdischarge status

When the battery voltage falls below  $V_{DL}$  during discharging in the normal status and the condition continues for the overdischarge detection delay time ( $t_{DL}$ ) or longer, the discharge control FET is turned off and discharging is stopped. This status is called the overdischarge status.

Under the overdischarge status, VDD pin and VM pin are shorted by  $R_{VMD}$  in this IC. The VM pin voltage is pulled up by  $R_{VMD}$ .

When connecting a charger in the overdischarge status, the battery voltage reaches  $V_{DL}$  or higher and this IC releases the overdischarge status if the VM pin voltage is below 0 V typ.

The battery voltage reaches the overdischarge release voltage ( $V_{DU}$ ) or higher and this IC releases the overdischarge status if the VM pin voltage is not below 0 V typ.

$R_{VMS}$  is not connected in the overdischarge status.

#### 3.1 With power-down function

Under the overdischarge status, when the VM pin voltage is 0.7 V typ. or higher, the power-down function works and the current consumption is reduced to the current consumption during power-down ( $I_{PDN}$ ). By connecting a battery charger, the power-down function is released when the VM pin voltage is 0.7 V typ. or lower.

- When a battery is not connected to a charger and the VM pin voltage  $\geq$  0.7 V typ., this IC maintains the overdischarge status even when the battery voltage reaches  $V_{DU}$  or higher.
- When a battery is connected to a charger and 0.7 V typ. > the VM pin voltage > 0 V typ., the battery voltage reaches  $V_{DU}$  or higher and this IC releases the overdischarge status.
- When a battery is connected to a charger and 0 V typ.  $\geq$  the VM pin voltage, the battery voltage reaches  $V_{DL}$  or higher and this IC releases the overdischarge status.

#### 3.2 Without power-down function

Under the overdischarge status, the power-down function does not work even when the VM pin voltage is 0.7 V typ. or higher.

- When a battery is not connected to a charger and the VM pin voltage  $\geq$  0.7 V typ., the battery voltage reaches  $V_{DU}$  or higher and this IC releases the overdischarge status.
- When a battery is connected to a charger and 0.7 V typ. > the VM pin voltage > 0 V typ., the battery voltage reaches  $V_{DU}$  or higher and this IC releases the overdischarge status.
- When a battery is connected to a charger and 0 V typ.  $\geq$  the VM pin voltage, the battery voltage reaches  $V_{DL}$  or higher and this IC releases the overdischarge status.

### 4. Discharge overcurrent status (discharge overcurrent 1, discharge overcurrent 2, load short-circuiting)

When a battery in the normal status is in the status where the VM pin voltage is equal to or higher than  $V_{DIOV1}$  because the discharge current is equal to or higher than the specified value and the status continues for the discharge overcurrent 1 detection delay time ( $t_{DIOV1}$ ) or longer, the discharge control FET is turned off and discharging is stopped. This status is called the discharge overcurrent status.

Under the discharge overcurrent status, VM pin and VSS pin are shorted by  $R_{VMS}$  in this IC. However, the VM pin voltage is the VDD pin voltage due to the load as long as the load is connected. When the load is disconnected, VM pin returns to the VSS pin voltage.

When the VM pin voltage returns to  $V_{RIOV}$  or lower, this IC releases the discharge overcurrent status.

$R_{VMD}$  is not connected in the discharge overcurrent status.

## 5. Charge overcurrent status

When a battery in the normal status is in the status where the VM pin voltage is equal to or lower than  $V_{C1OV}$  because the charge current is equal to or higher than the specified value and the status continues for the charge overcurrent detection delay time ( $t_{C1OV}$ ) or longer, the charge control FET is turned off and charging is stopped. This status is called the charge overcurrent status.

This IC releases the charge overcurrent status when the discharge current flows and the VM pin voltage is 0.35 V typ. or higher by removing the charger.

The charge overcurrent detection does not function in the overdischarge status.

## 6. 0 V battery charge enabled

This function is used to recharge a connected battery whose voltage is 0 V due to self-discharge. When the 0 V battery charge starting charger voltage ( $V_{0CHA}$ ) or a higher voltage is applied between the EB+ and EB- pins by connecting a charger, the charge control FET gate is fixed to the VDD pin voltage.

When the voltage between the gate and source of the charge control FET becomes equal to or higher than the threshold voltage due to the charger voltage, the charge control FET is turned on to start charging. At this time, the discharge control FET is off and the charging current flows through the internal parasitic diode in the discharge control FET. When the battery voltage becomes equal to or higher than  $V_{DL}$ , this IC returns to the normal status.

- Caution**
1. **Some battery providers do not recommend charging for a completely self-discharged lithium-ion rechargeable battery. It depends on the characteristics of the lithium-ion rechargeable battery to be used; therefore, please ask the battery provider to determine whether to enable or inhibit the 0 V battery charge.**
  2. **The 0 V battery charge has higher priority than the charge overcurrent detection function. Consequently, a product in which use of the 0 V battery charge is enabled charges a battery forcibly and the charge overcurrent cannot be detected when the battery voltage is lower than  $V_{DL}$ .**

## 7. 0 V battery charge inhibited

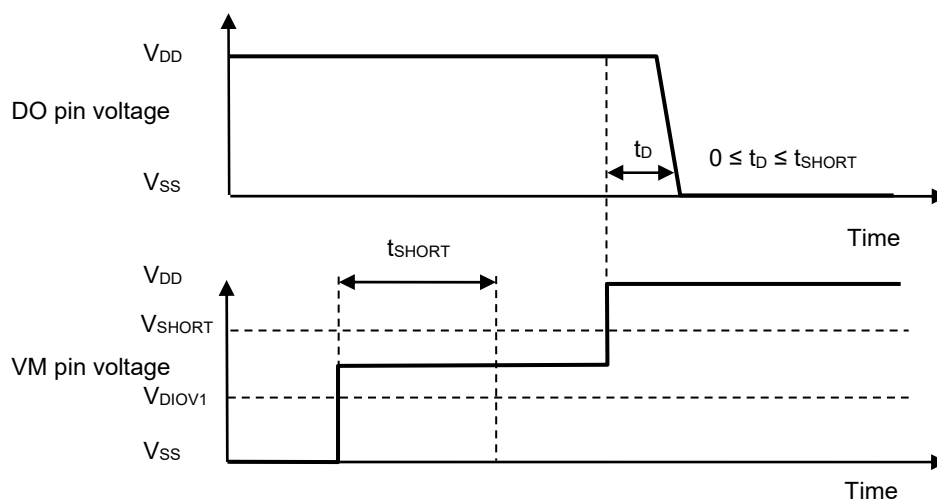
This function inhibits charging when a battery that is internally short-circuited (0 V battery) is connected. When the battery voltage is the 0 V battery charge inhibition battery voltage ( $V_{0INH}$ ) or lower, the charge control FET gate is fixed to the EB- pin voltage to inhibit charging. When the battery voltage is  $V_{0INH}$  or higher, charging can be performed.

- Caution**
- Some battery providers do not recommend charging for a completely self-discharged lithium-ion rechargeable battery. It depends on the characteristics of the lithium-ion rechargeable battery to be used; therefore, please ask the battery provider to determine whether to enable or inhibit the 0 V battery charge.**

## 8. Delay circuit

The detection delay times are determined by dividing a clock of approximately 4 kHz by the counter.

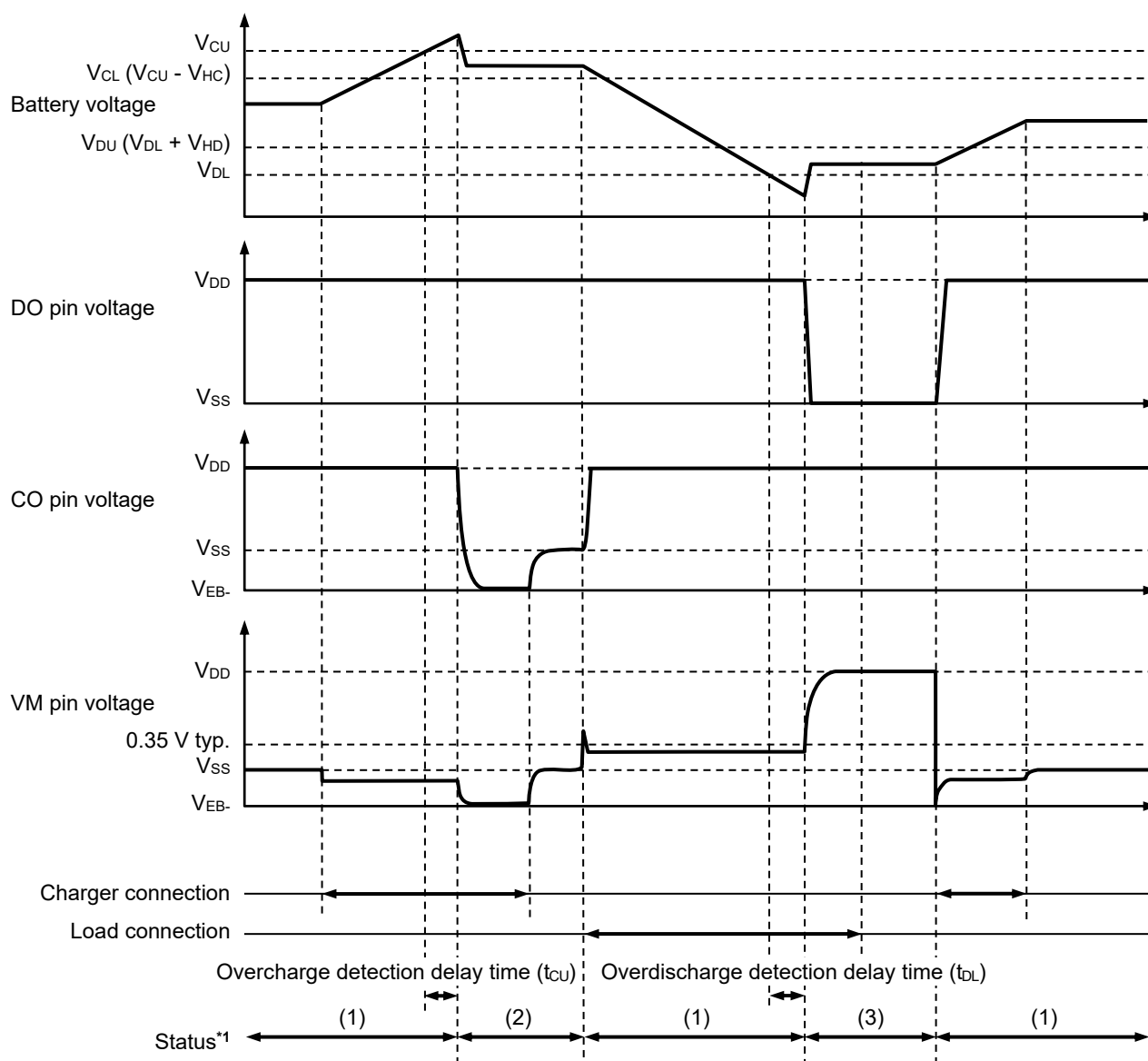
**Remark**  $t_{DIOV1}$ ,  $t_{DIOV2}$  and  $t_{SHORT}$  start when  $V_{DIOV1}$  is detected. When  $V_{DIOV2}$  or  $V_{SHORT}$  is detected over  $t_{DIOV2}$  or  $t_{SHORT}$  after the detection of  $V_{DIOV1}$ , the discharge control FET is turned off within  $t_{DIOV2}$  or  $t_{SHORT}$  of each detection.



**Figure 8**

## ■ Timing Charts

### 1. Overcharge detection, overdischarge detection

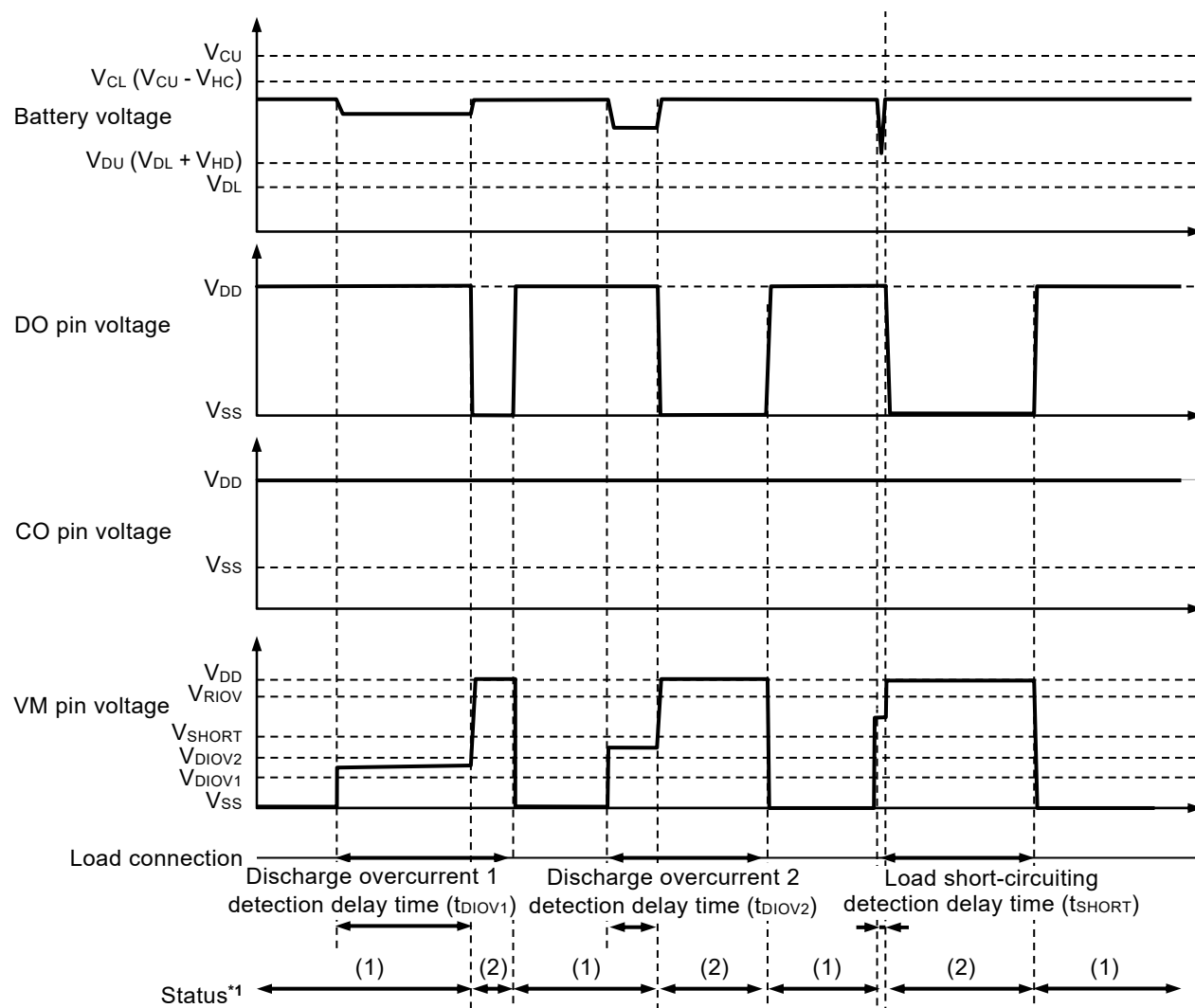


- \*1. (1): Normal status  
 (2): Overcharge status  
 (3): Overdischarge status

**Remark** The charger is assumed to charge with a constant current.

**Figure 9**

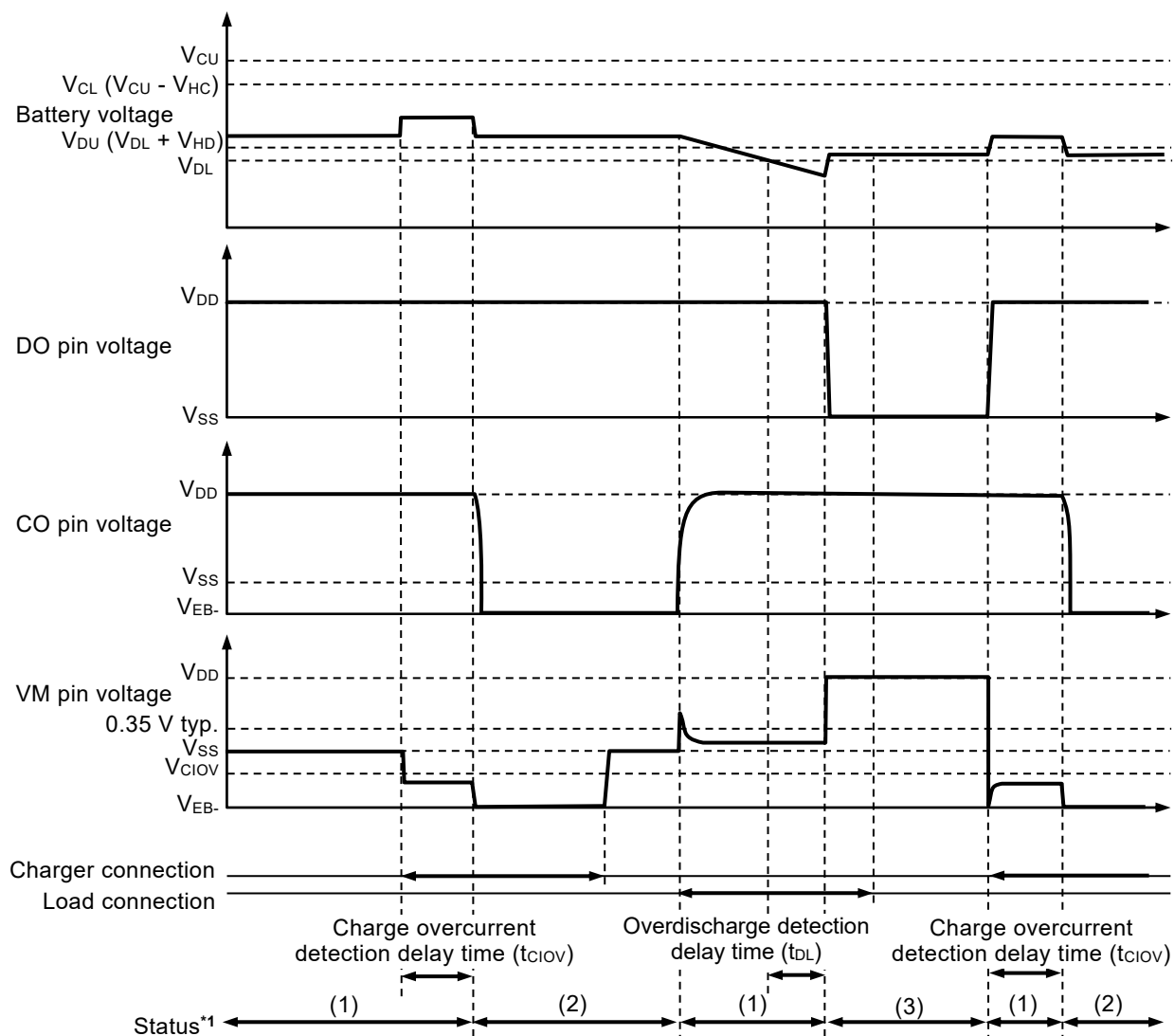
## 2. Discharge overcurrent detection



\*1. (1): Normal status  
 (2): Discharge overcurrent status

Figure 10

### 3. Charge overcurrent detection



- \*1. (1): Normal status  
 (2): Charge overcurrent status  
 (3): Overdischarge status

**Remark** The charger is assumed to charge with a constant current.

**Figure 11**

## ■ Battery Protection IC Connection Example

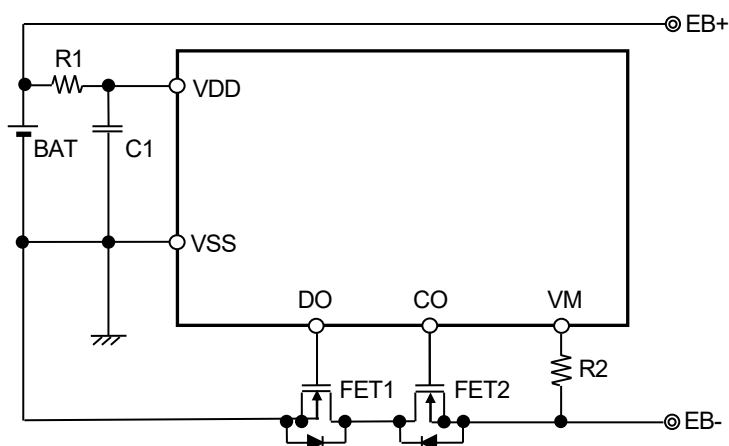


Figure 12

Table 13 Constants for External Components

| Symbol | Part              | Purpose                                                        | Min.         | Typ.         | Max.            | Remark                                                     |
|--------|-------------------|----------------------------------------------------------------|--------------|--------------|-----------------|------------------------------------------------------------|
| FET1   | N-channel MOS FET | Discharge control                                              | -            | -            | -               | Threshold voltage $\leq$ Overdischarge detection voltage*1 |
| FET2   | N-channel MOS FET | Charge control                                                 | -            | -            | -               | Threshold voltage $\leq$ Overdischarge detection voltage*1 |
| R1     | Resistor          | ESD protection, for power fluctuation                          | 330 $\Omega$ | 330 $\Omega$ | 1 k $\Omega$ *2 | -                                                          |
| C1     | Capacitor         | For power fluctuation                                          | 0.1 $\mu$ F  | 0.1 $\mu$ F  | 1 $\mu$ F       | -                                                          |
| R2     | Resistor          | ESD protection, Protection for reverse connection of a charger | 270 $\Omega$ | 470 $\Omega$ | 1.5 k $\Omega$  | -                                                          |

\*1. If a FET with a threshold voltage equal to or higher than the overdischarge detection voltage is used, discharging may be stopped before overdischarge is detected.

\*2. Accuracy of overcharge detection voltage is guaranteed by  $R1 = 330 \Omega$ . Connecting resistors with other values will worsen the accuracy.

**Caution**

1. The constants may be changed without notice.
2. It has not been confirmed whether the operation is normal or not in circuits other than the connection example. In addition, the connection example and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.

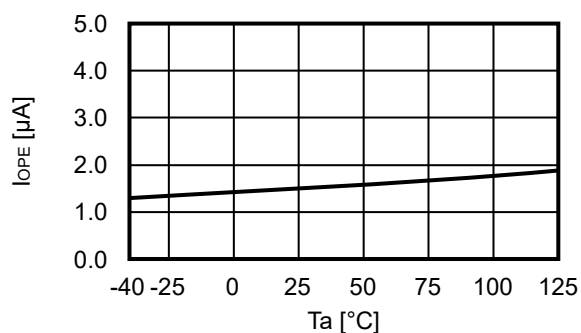
## ■ Precautions

- The application conditions for the input voltage, output voltage, and load current should not exceed the power dissipation.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- ABLIC Inc. claims no responsibility for any and all disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

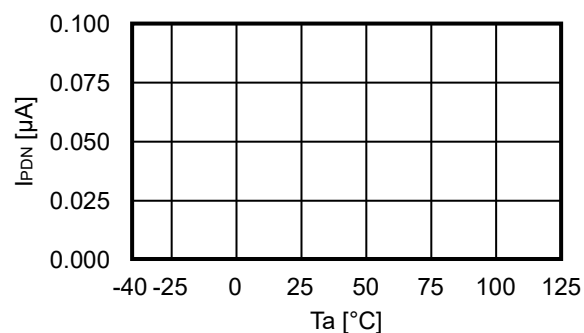
## ■ Characteristics (Typical Data)

### 1. Current consumption

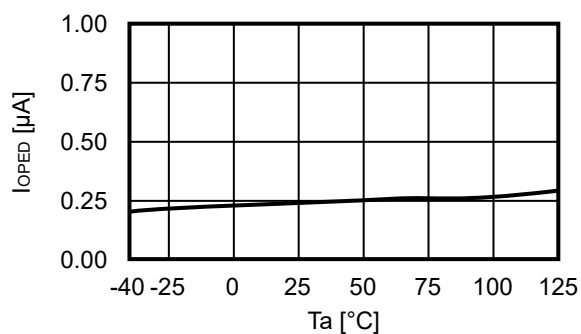
1.1  $I_{OPE}$  vs.  $T_a$



1.2  $I_{PDN}$  vs.  $T_a$

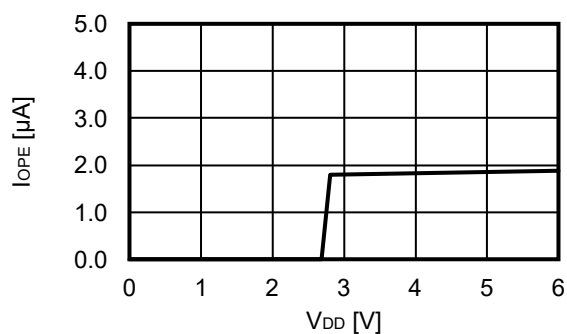


1.3  $I_{OPED}$  vs.  $T_a$

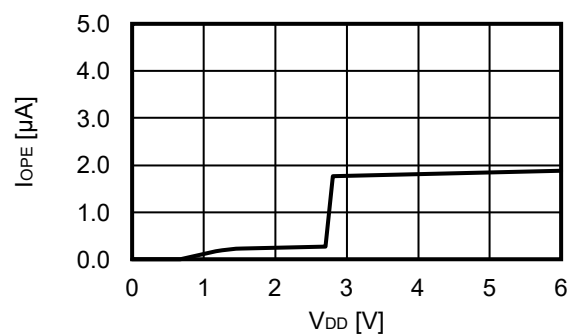


1.4  $I_{OPE}$  vs.  $V_{DD}$

1.4.1 With power-down function

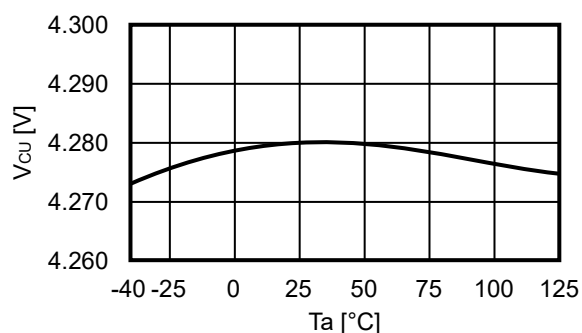


1.4.2 Without power-down function

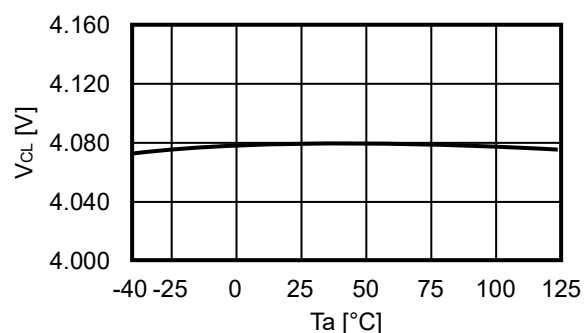


## 2. Detection voltage, release voltage

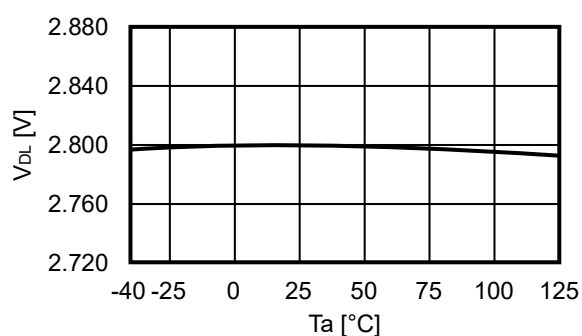
**2.1  $V_{CU}$  vs.  $T_a$**



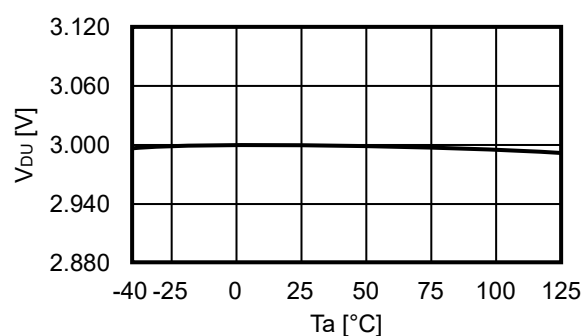
**2.2  $V_{CL}$  vs.  $T_a$**



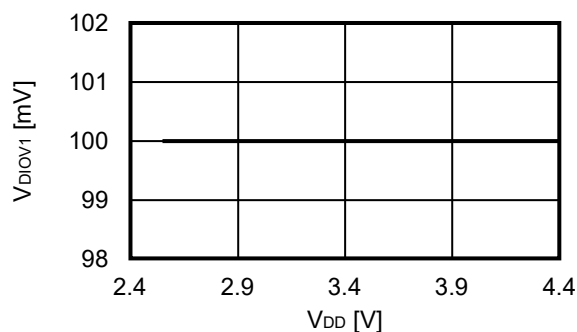
**2.3  $V_{DL}$  vs.  $T_a$**



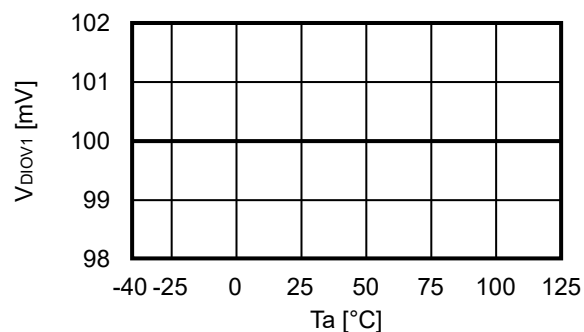
**2.4  $V_{DU}$  vs.  $T_a$**



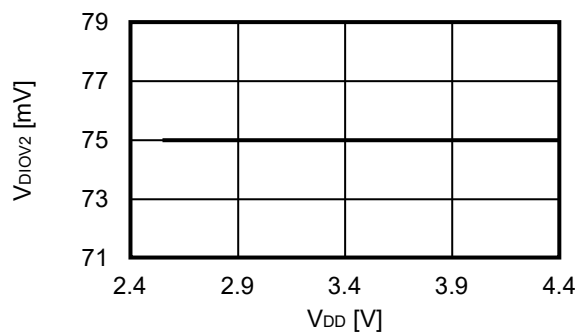
**2.5  $V_{DIOV1}$  vs.  $V_{DD}$**



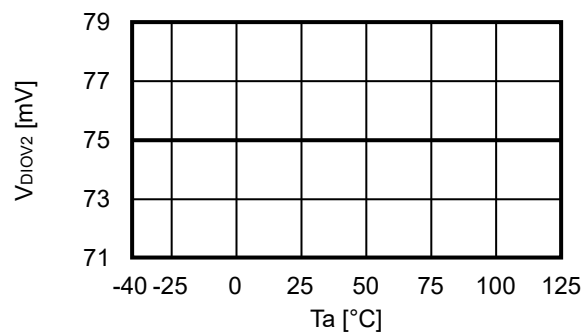
**2.6  $V_{DIOV1}$  vs.  $T_a$**



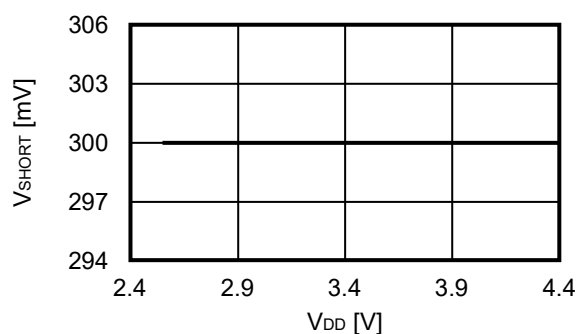
**2.7  $V_{DIOV2}$  vs.  $V_{DD}$**



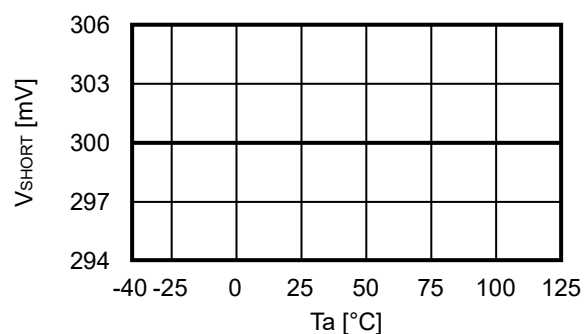
**2.8  $V_{DIOV2}$  vs.  $T_a$**



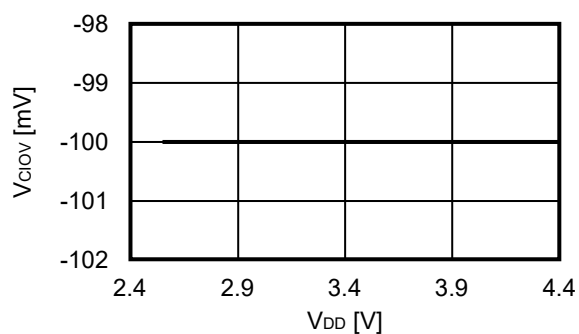
**2. 9  $V_{\text{SHORT}}$  vs.  $V_{\text{DD}}$**



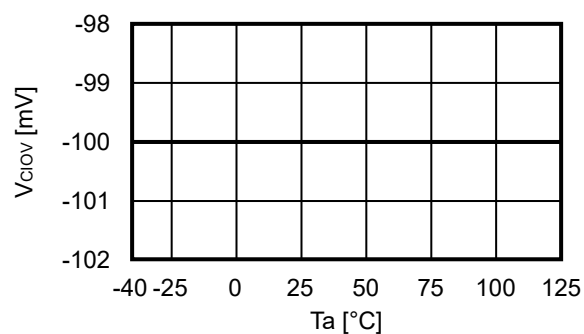
**2. 10  $V_{\text{SHORT}}$  vs.  $T_a$**



**2. 11  $V_{\text{CLOV}}$  vs.  $V_{\text{DD}}$**

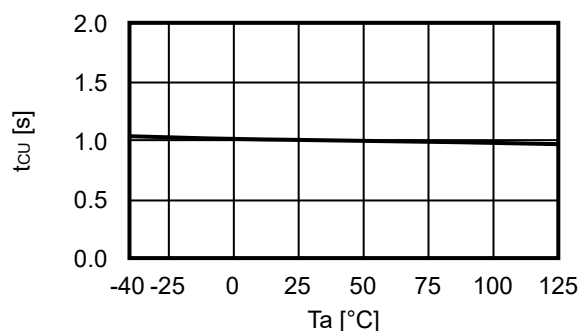


**2. 12  $V_{\text{CLOV}}$  vs.  $T_a$**

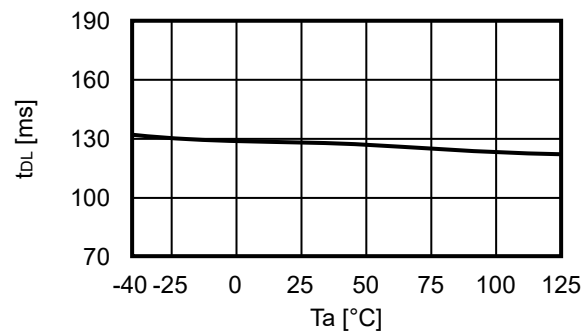


### 3. Delay time

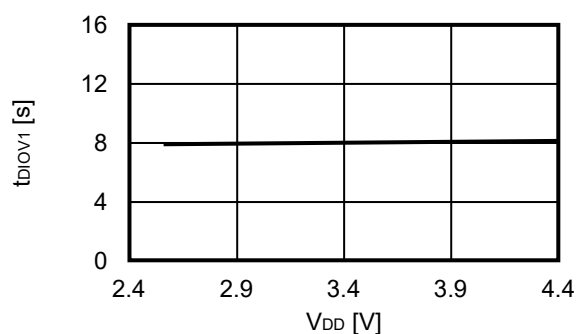
**3.1  $t_{CU}$  vs.  $T_a$**



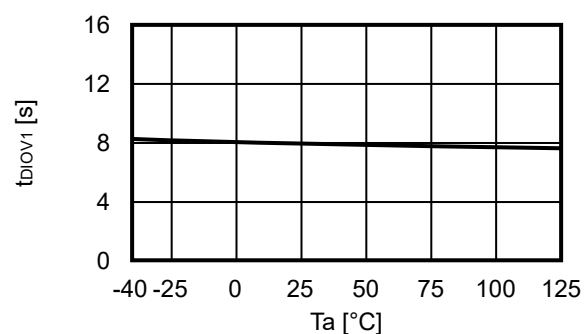
**3.2  $t_{DL}$  vs.  $T_a$**



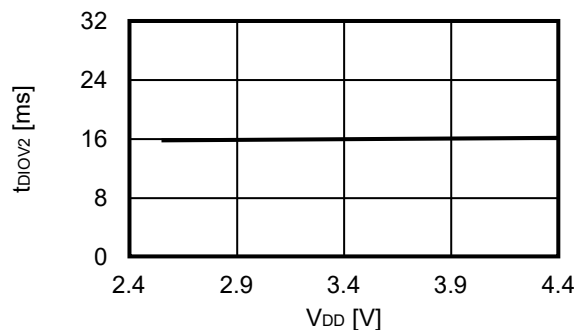
**3.3  $t_{DIOV1}$  vs.  $V_{DD}$**



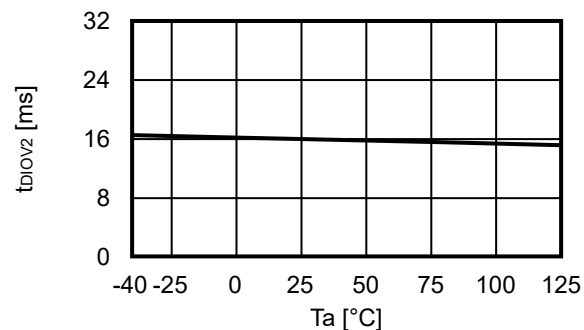
**3.4  $t_{DIOV1}$  vs.  $T_a$**



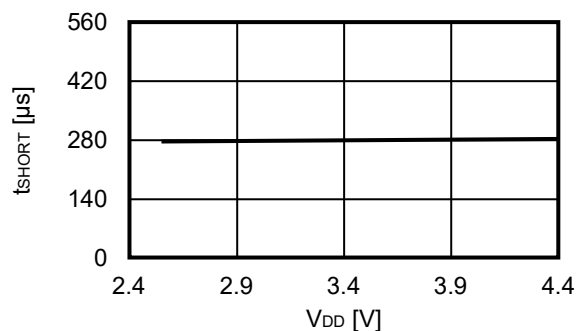
**3.5  $t_{DIOV2}$  vs.  $V_{DD}$**



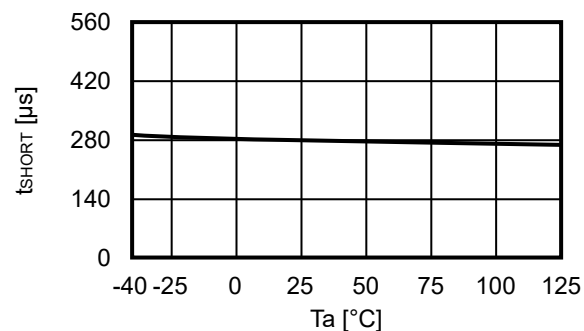
**3.6  $t_{DIOV2}$  vs.  $T_a$**



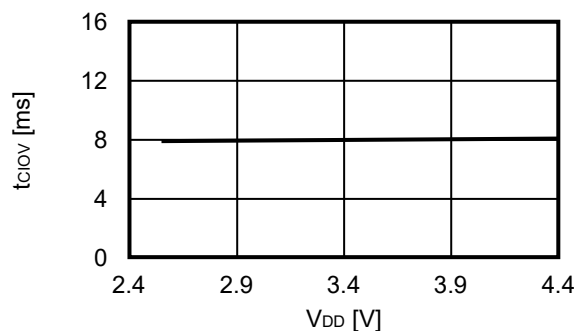
**3.7  $t_{SHORT}$  vs.  $V_{DD}$**



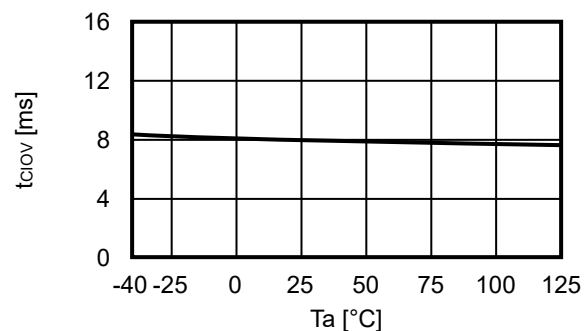
**3.8  $t_{SHORT}$  vs.  $T_a$**



**3. 9  $t_{CLOV}$  vs.  $V_{DD}$**

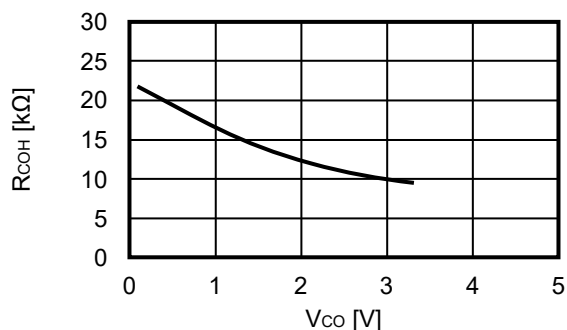


**3. 10  $t_{CLOV}$  vs.  $T_a$**

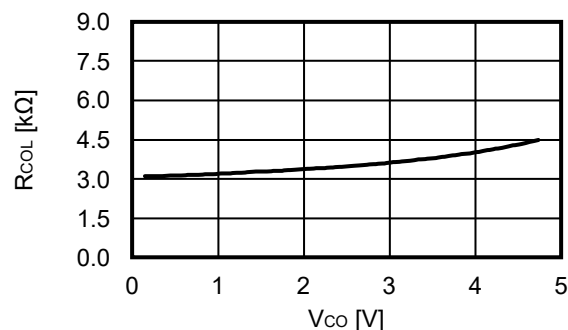


#### 4. Output resistance

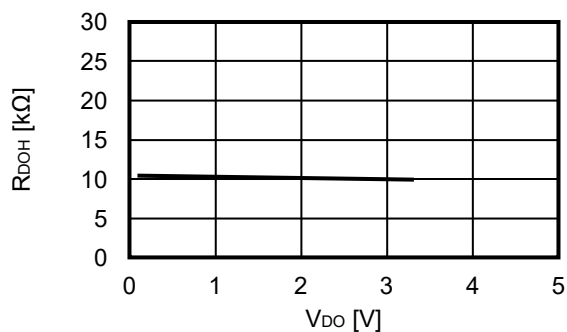
**4. 1  $R_{COH}$  vs.  $V_{CO}$**



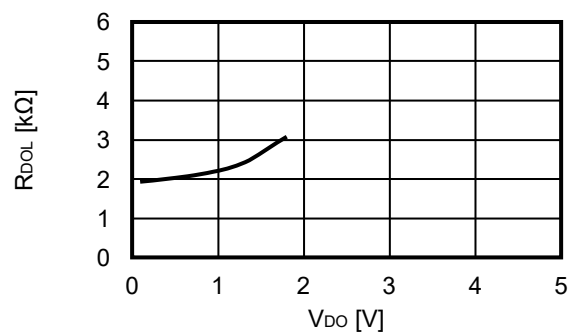
**4. 2  $R_{COL}$  vs.  $V_{CO}$**



**4. 3  $R_{DOH}$  vs.  $V_{DO}$**

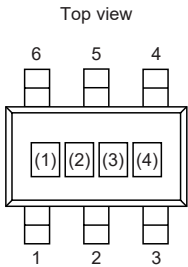


**4. 4  $R_{DOL}$  vs.  $V_{DO}$**



■ **Marking Specifications**

**1. SOT-23-6**



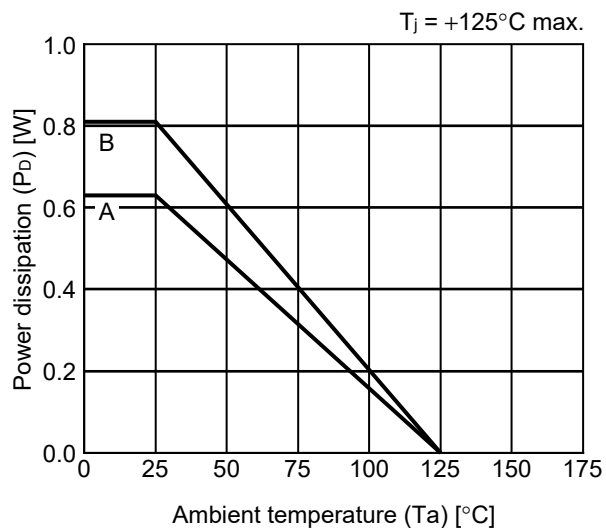
(1) to (3): Product code (Refer to **Product name vs. Product code**)  
(4): Lot number

**Product name vs. Product code**

| Product Name       | Product Code |     |     |
|--------------------|--------------|-----|-----|
|                    | (1)          | (2) | (3) |
| S-19161AACA-M6T1U7 | b            | N   | D   |

## ■ Power Dissipation

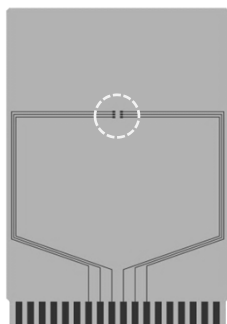
### SOT-23-6



| Board | Power Dissipation ( $P_D$ ) |
|-------|-----------------------------|
| A     | 0.63 W                      |
| B     | 0.81 W                      |
| C     | -                           |
| D     | -                           |
| E     | -                           |

# SOT-23-3/3S/5/6 Test Board

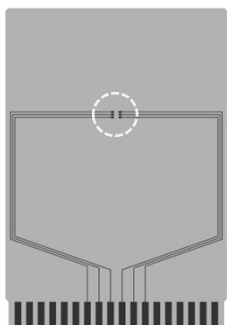
(1) Board A



 IC Mount Area

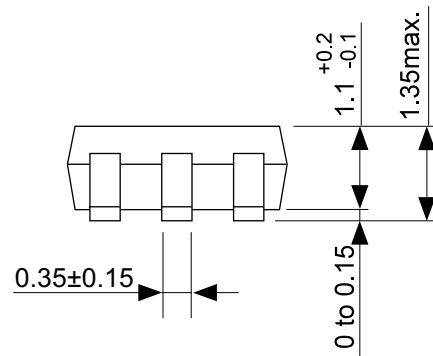
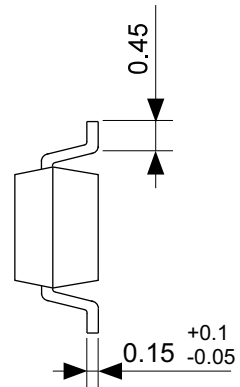
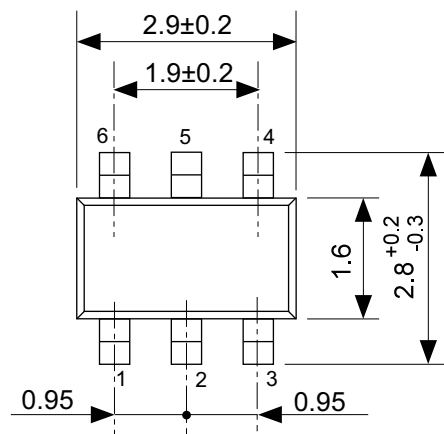
| Item                        |   | Specification                               |
|-----------------------------|---|---------------------------------------------|
| Size [mm]                   |   | 114.3 x 76.2 x t1.6                         |
| Material                    |   | FR-4                                        |
| Number of copper foil layer |   | 2                                           |
| Copper foil layer [mm]      | 1 | Land pattern and wiring for testing: t0.070 |
|                             | 2 | -                                           |
|                             | 3 | -                                           |
|                             | 4 | 74.2 x 74.2 x t0.070                        |
| Thermal via                 |   | -                                           |

(2) Board B



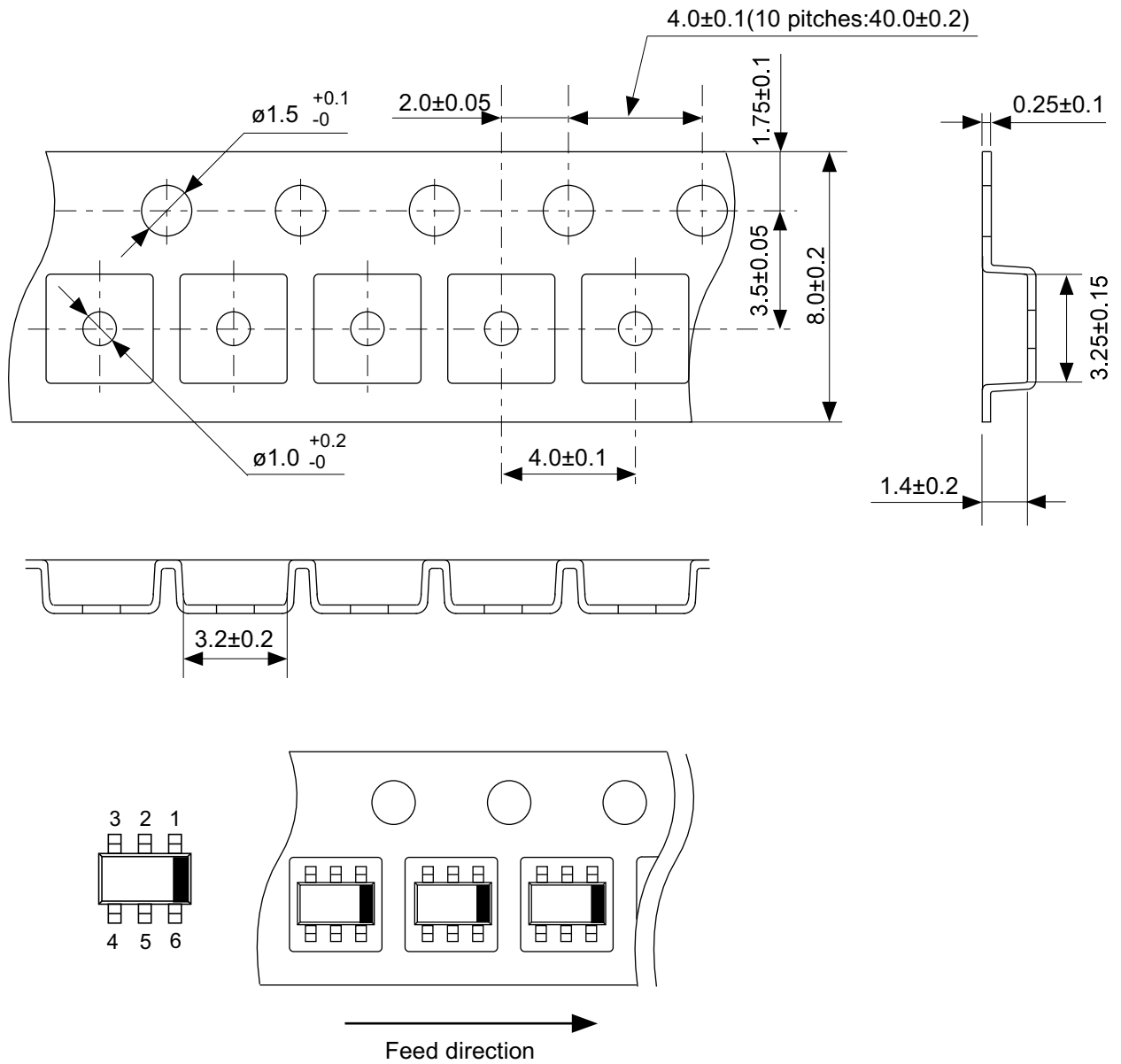
| Item                        |   | Specification                               |
|-----------------------------|---|---------------------------------------------|
| Size [mm]                   |   | 114.3 x 76.2 x t1.6                         |
| Material                    |   | FR-4                                        |
| Number of copper foil layer |   | 4                                           |
| Copper foil layer [mm]      | 1 | Land pattern and wiring for testing: t0.070 |
|                             | 2 | 74.2 x 74.2 x t0.035                        |
|                             | 3 | 74.2 x 74.2 x t0.035                        |
|                             | 4 | 74.2 x 74.2 x t0.070                        |
| Thermal via                 |   | -                                           |

No. SOT23x-A-Board-SD-2.0



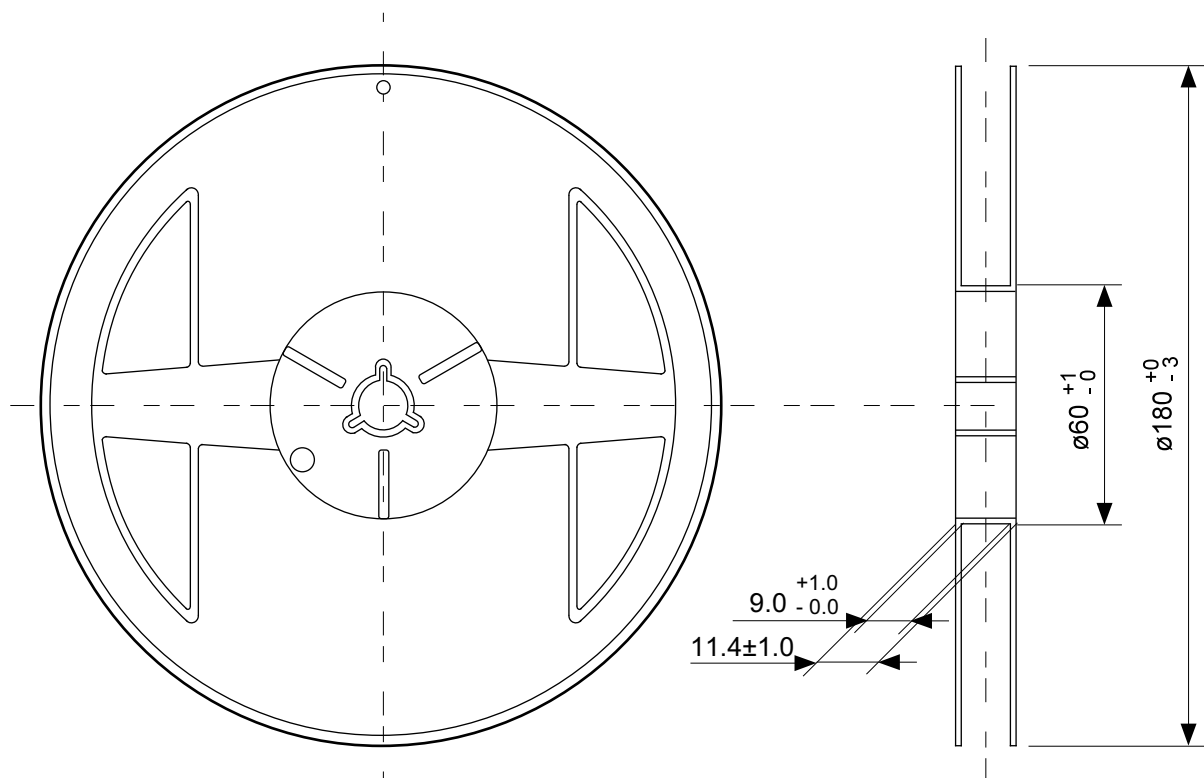
No. MP006-A-P-SD-2.1

|            |                                                                                       |
|------------|---------------------------------------------------------------------------------------|
| TITLE      | SOT236-A-PKG Dimensions                                                               |
| No.        | MP006-A-P-SD-2.1                                                                      |
| ANGLE      |  |
| UNIT       | mm                                                                                    |
|            |                                                                                       |
| ABLIC Inc. |                                                                                       |

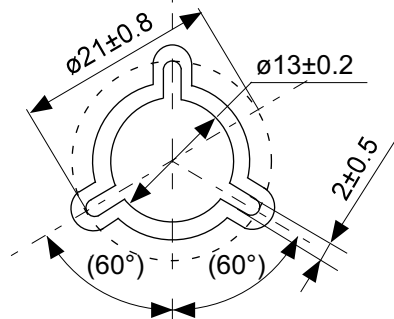


No. MP006-A-C-SD-3.1

|            |                       |
|------------|-----------------------|
| TITLE      | SOT236-A-Carrier Tape |
| No.        | MP006-A-C-SD-3.1      |
| ANGLE      |                       |
| UNIT       | mm                    |
|            |                       |
| ABLIC Inc. |                       |



Enlarged drawing in the central part



No. MP006-A-R-SD-3.0

|            |                  |     |       |
|------------|------------------|-----|-------|
| TITLE      | SOT236-A-Reel    |     |       |
| No.        | MP006-A-R-SD-3.0 |     |       |
| ANGLE      |                  | QTY | 3,000 |
| UNIT       | mm               |     |       |
|            |                  |     |       |
| ABLIC Inc. |                  |     |       |

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2.4-2019.07